

GateMate™ FPGA Datasheet

CCGM1A1



DS1001 Datasheet May 2022



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About this Document

This datasheet covers all features of the Cologne Chip GateMate $^{\mathsf{TM}}$ FPGA Series and is part of the GateMate $^{\mathsf{TM}}$ documentation collection.

For more information please refer to the following documents:

- Technology Brief of GateMate[™] FPGA
- DS1002 GateMate[™] FPGA Programmer Board Ver. 1.3 Datasheet 🗷
- DS1003 GateMate[™] FPGA Evaluation Board Ver. 3.1 Datasheet 🗗
- UG1001 GateMate[™] FPGA Primitives Library 🗷
- UG1002 GateMate[™] FPGA Toolchain Installation User Guide 🗹

Cologne Chip provides a comprehensive technical support. Please visit our website for more information or contact our support team.

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Revision History

This Datasheet is constantly updated. The latest version of the document can be found following the link below:

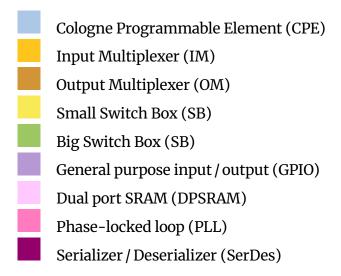
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| Date | Remarks |
|---------------|---|
| May 2022 | • Sections 3.1.2 (Synthesis), 3.1.3 (Implementation) and 3.1.4 (Configuration) from page 47 added. |
| | Additional explanation to the power-on reset module: Section 3.2.1 from page 54 expanded. |
| | Section 3.2.1 from page 34 expanded.Sections 3.2.2 and 3.2.2 from page 55 added. |
| | Reset characteristics in Table 4.6 on page 76 added. |
| | Clock pins renamed from CLK[4:1] to CLK[3:0] (BGA pins N14, P12, P14 and R13). |
| February 2022 | Updated workflow description in Section 3.1.1 from page 45 with Yosys support added. |
| October 2021 | Additional explanation to Section 2.4.8 on page 32. |
| July 2021 | Expanded Block RAM documentation in Section 2.4 from page 23. |
| | Updated maximum PLL output frequencies in Section 2.5 on page 41. |
| December 2020 | Expanded JTAG interface documentation in Section 3.4 from page 63. |
| | Updated package height and tolerances in Figure 6.1 on page 92. |
| October 2020 | Updated 324-ball FBGA package to final pinout: |
| | FBGA pinout in Figures 5.1 and 5.2 on pages 78 and 78. Pin types and pin lists in Tables 5.1 and 5.2 from page 79. |
| February 2020 | Initial pre-release. |



General Remarks to Notations

- 1. The decimal point is written as a point (e.g., 1.23). Thousands separators are written with thin space.
- 2. Numerical values have different notations for various number systems; e.g., the hexadecimal value 0×0 is 0×1001001 in binary and 201 in decimal notation.
- 3. The prefix 'kilo' is written k for the meaning of 1000 and it is written K for the meaning of 1024.
- 4. Functional elements of the GateMateTM FPGA have certain colors. These are:



5. general purpose input / output (GPIO) banks and special pin functions of the GateMate $^{\mathsf{TM}}$ FPGA are grouped by certain colors. Please see Section 5.2 on page 79 for an overview.

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Chapter 1

Introduction

1.1 Introduction

The Cologne Chip GateMateTM FPGA Series is a family of small to medium-sized FPGAs that addresses all requirements of typical applications. The programmable silicon can be used from low power to high speed applications and thus in a wide range of fields: industry, automation, communication, security, automative, Internet of Things (IoT), artificial intelligence (AI), and lots more.

Logic capacity, power consumption, package size and printed circuit board (PCB) compatibility are optimized for a wide range of applications. As these FPGAs combine various features with lowest cost in the market, the devices are well suited from university projects to high volume applications. Because of the outstanding ratio of circuit size to cost, even price sensitive applications can also now take advantage of FPGAs. The devices are manufactured using GlobalfoundriesTM 28 nm Super Low Power (SLP) process in Dresden, Germany. The GateMateTM FPGA program is supported by the German Federal Ministry for Economic Affairs and Energy as part of the Important Project of Common Eu-

Supported by:



on the basis of a decision by the German Bundestag

ropean Interest (IPCEI) on Microelectronics project, which is also supported by the European Commission.

Cologne Chip is a semiconductor company based in Cologne, Germany. The company, which celebrates its 25th anniversary in 2020, has excellent industry knowledge and an experienced team of developers. The design and manufacturing location *Made in Germany* represents a unique selling proposition of globally competitive FPGAs in the market.

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Introduction

Cologne Chip offers and supports a variety of development tools:

- The GateMateTM FPGA Evaluation Board is a feature-rich, ready-to-use development platform that serves as a reference design and for a direct entry into application development.
- With the help of the GateMate TM FPGA Programmer, the FPGA can be configured in various ways.

Cologne Chip provides a comprehensive technical support. Please visit our website for more information or contact our support and sales teams.

1.2 Features

- · Novel programmable element architecture
 - · 20,480 programmable elements for combinatorial and sequential logic
 - 20,480 8-input LUT-trees / 40,960 4-input LUT-trees
 - 40,960 Latches / Flip-flops within programmable elements
 - · Each programmable element configurable as:
 - · 1-bit full adder
 - · 2-bit full adder or
 - 2×2-bit multiplier
 - · Dedicated logic and routing for fast arithmetic and arbitrary-sized multipliers
- 9 general purpose input / output (GPIO) banks
 - 162 user-configurable GPIOs
 - All GPIOs configurable as single-ended or LVDS differential pairs
 - · Double data rate (DDR) registers in I/O cells
 - I/O voltage range from 1.2 to 2.5 V
- 4 clock generators (PLL)
 - Maximum oscillator frequency from 1.000 MHz to 2.500 MHz
 - Maximum PLL output frequency from 250 MHz to 416.75 MHz
- · 2.5 Gb/s Serializer / Deserializer (SerDes) controller
- Flexible memory resources
 - 1,310,720 total RAM bits distributed over 32 SRAM blocks
 - Each RAM block configurable as two independent 20 Kbit blocks or single 40 Kbit block
 - · Simple or True Dual Port (SDP / TDP) or FIFO mode
 - Data width from 1 bit up to 40 bits (TDP) or 80 bits (SDP)
 - Bit-wide write enable
 - Error checking and correcting (ECC) for certain bit widths

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- · Flexible device configuration
 - Configuration bank switchable to user I/O
 - JTAG interface with bypass to SPI interface
 - · Active / passive SPI interface for singe-, dual- and quad-mode operation

Introduction

- · SPI flash interface in active mode
- · Multi-chip configuration from single source
- · Application modes: low power, economy, speed
 - Mode adjustable on each chip via core voltage
 - Core voltage range from 0.9 to 1.1V
- Package
 - * $15{\times}15\,\text{mm}$ 324 balls 0.8 mm fine pitch Ball Grid Array (FBGA) package
 - Only 2 signal layers required on PCB

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Chapter 2 Architecture

2.1 GateMate™ FPGA Overview

The basic functional elements of GateMateTM FPGA are set up in an array structure of 160×128 elements called Cologne Programmable Element (CPE) as described in Section 2.2.

All CPEs are interconnected by a routing structure of 132×164 so called Switch Boxes (SBs) as described in Section 2.6.

Additional functional blocks are dual port SRAMs (DPSRAMs), phase-locked loops (PLLs), general purpose input / output (GPIO) cells, SPI configuration and data flash interface, JTAG interface and Serializer / Deserializer (SerDes) interface.

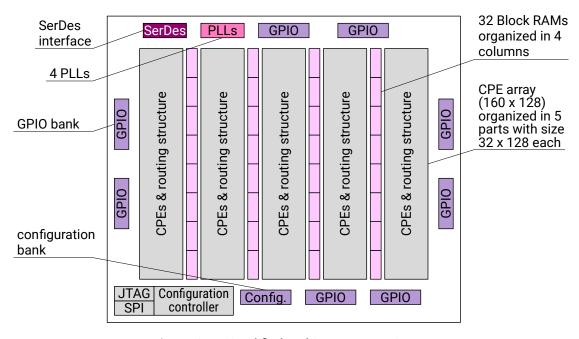


Figure 2.1: Simplified architecture overview

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2.2 Cologne Programmable Element (CPE)

General purpose combinatorial and sequential circuits are implemented using CPEs. The CCGM1A1 has 20,480 CPEs arranged in a 160 \times 128 matrix. Each CPE can be set up to the following combinatorial functions:

- Dual 4 inputs with 2-input lookup table (LUT-2) tree each
- 8 inputs with LUT-2 tree
- 6 inputs with 4-input multiplexer (MUX-4) function
- 1-bit or 2-bit full adder, expandable to any length in horizontal or vertical arrangement
- 2×2 -bit multiplier, expandable to any multiplier size

Figure 2.2 illustrates the general structure of a CPE. General combinatorial and sequential functions are supported from fast signal path routing. In addition, the DPSRAM blocks of GateMateTM FPGA, as described in Chapter 2.4, require some CPE ports RAM_I[2:1] and RAM_0[2:1] for CPE-to-SRAM connection.

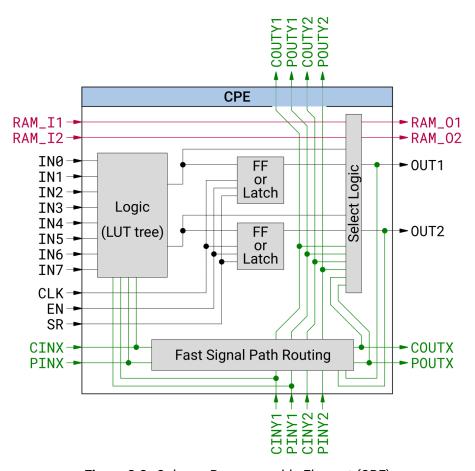


Figure 2.2: Cologne Programmable Element (CPE)

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Two CPE outputs 0UT1 and 0UT2 are available and each can use a Flip-Flop or Latch function.

Furthermore, the CPEs include fast signal routing paths, so-called carry & propagation signal lines (CP-lines). Typically, they are used for fast clock and carry propagation in adder and multiplier functions, e.g., fast CPE to adjacent CPE connections, or even fast signal propagation over any span of CPEs.

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2.3 General purpose input / output (GPIO)

The GateMateTM FPGA offers up to 162 general purpose input / output pins (GPIOs). These are organized in signal pairs, so called *pad cells*, which can either operate as two independent, bidirectional single-ended signals or they can be set up as bidirectional low-voltage differential signaling (LVDS). Figures 2.3 and 2.4 show the structure of the pad cells and their interconnection to the FPGA elements.

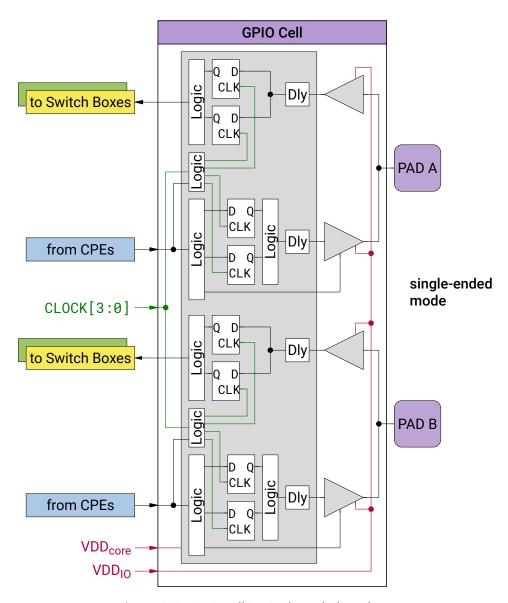


Figure 2.3: GPIO cell in single-ended mode

Nine pad cells build up a GPIO bank as shown in Figure 2.5 on page 22. Eight banks and another optional bank ¹ are available.

The FPGA configuration pins are arranged within the ninth GPIO bank. These pins can be used as normal GPIO bank after configuration process.



The single-ended GPIO support the low voltage CMOS (LVCMOS) standard up to 2.5 V nominal supply voltage, compliant to the standards JESD8-5 (2.5 V) and JESD8-7 (1.8 V and 1.2 V).

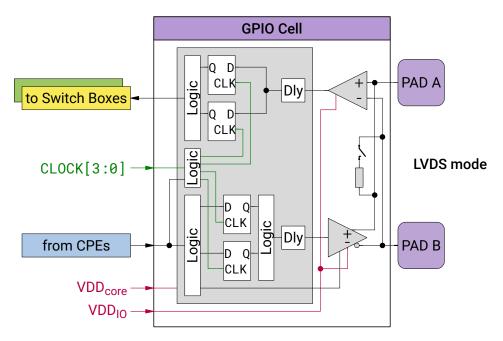


Figure 2.4: GPIO cell in LVDS mode

The single-ended GPIO pins have the following output features:

- 0/1/high-Z
- · Slew-rate control
- Driver strength 3 mA, 6 mA, 9 mA and 12 mA
- · 2 Flip-Flops
- · Programmable delay line

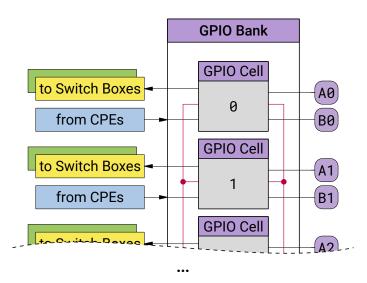
The single-ended GPIO pins have the following input features:

- Schmitt-trigger input
- Pull-up / pull-down resistors or keeper functionality
- Input receiver disable for power reduction
- · 2 Flip-Flops
- · Programmable delay line

If a pad cell is used in its LVDS mode, both pads can be used together only. The LVDS pad is compliant to the LVDS 2.5 V standard. It further can operate down to 1.8 V nominal supply voltage, with common mode voltage $V_{\rm DD}/2$. The LVDS input receiver can be used as voltage comparator.

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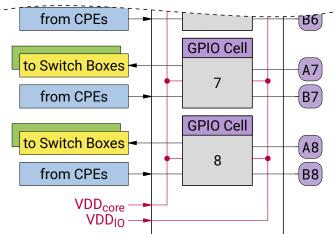


Figure 2.5: GPIO bank



2.4 Embedded Block RAM

2.4.1 Block RAM Overview

The GateMateTM FPGA contains a number of embedded volatile memory cells which are organized as configurable 40 kbit dual port SRAM (DPSRAM) cells. These random-access memory (RAM) cells are arranged in columns between the CPE array and routing structure as illustrated in Figure 2.6. Block RAMs have an address (x,y) with x = 0..3 and y = 0..7.

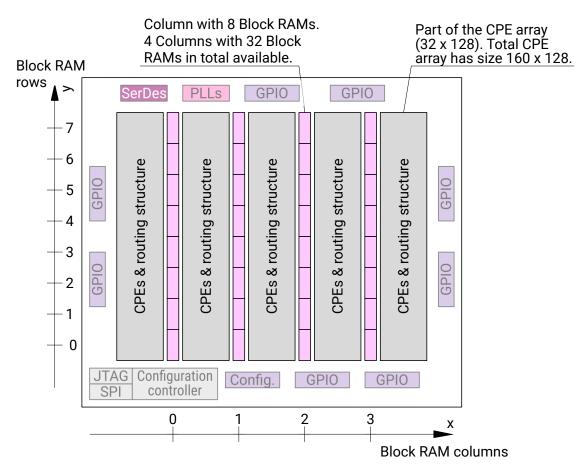


Figure 2.6: Block RAM arrangement

Each Block RAM cell can be configured as a single 40K or two independent 20K DPSRAM cells. Both allow usage of the memory in true dual port (TDP) or simple dual port (SDP) mode.

The GateMateTM Block RAM features include:

- Data widths from 1 bit up to 40 bits in TDP mode or 80 bits in SDP mode.
- Bit-wide write enable allows a bit-wise writing of incoming data and can be used when for example interfacing with a microprocessor.

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- Each port has optional output registers. When enabled, validity of the output data gets delayed by one clock cycle. This feature is particularly helpful when dealing with critical paths.
- Each port provides an error checking and correcting (ECC) module for data protection against unintended changes. Error correction is able to correct one bit errors and detect two bit errors.
- A memory cascading feature connects adjacent RAM cells to form a larger array. This
 feature enables the instantiation of deeper or wider memories and a flexible forwarding of clocks, address and control signals.
- Two adjacent Block RAMs can be combined to one deeper $64K \times 1$ memory by extending the cascade feature to forward data and bitmask signals as well.
- Contents of the Block RAM cells can be initialized during configuration, e.g., to build read-only memory (ROM).
- · All clock, enable and write enable signals can be inverted individually.
- Each Block RAM can be used as a first-in, first-out memory (FIFO) in asynchronous or synchronous mode with dedicated status signals for FIFO monitoring and reset.

Tables 2.1 and 2.2 show the available address and data bus width configurations as well as the ECC availability for both 20K and 40K configurations in SDP and TDP modes.

Table 2.1: 20K configurations

Table 2.2: 40K configurations

| Configuration | TDP | SDP | ECC | Configuration | TDP | SDP | ECC |
|-----------------------------|---------|-----|-----|---------------------|-----|-----|-----|
| (RAM size per 2 | 0K bloc | k) | | $32K \times 1$ bit | ✓ | 1 | X |
| $16K \times 1bit$ | ✓ | ✓ | X | $16K \times 2 bit$ | ✓ | ✓ | X |
| $8K\times \ 2bit$ | ✓ | ✓ | X | $8K \times 5$ bit | ✓ | ✓ | X |
| $4K \times 5$ bit | ✓ | ✓ | X | $4K\times 10 \ bit$ | ✓ | ✓ | X |
| $2K\times10bit$ | ✓ | ✓ | X | $2K\times 20\;bit$ | ✓ | ✓ | X |
| $1K\times20\:bit$ | ✓ | ✓ | X | $1K\times 40\;bit$ | ✓ | ✓ | 1 |
| $512 \times 40 \text{ bit}$ | × | 1 | 1 | 512×80 bit | × | 1 | 1 |

2.4.2 Block RAM Architecture

A Block RAM cell has a maximum storage capacity of 40 Kbits and can be configured as a single 40K cell or two independent 20K cells. It contains two independent ports A and B that are implemented in the form of the four input signal groups A0, B0, A1 and B1. Configured as two independent 20K cells, A0, B0, A1 and B1 represent ports A and B for the two cells. In the 40K configuration, A0+A1 and B0+B1 are combined to represent both ports A and B. Figure 2.7 shows the basic structure of a single Block RAM cell with its horizontal input and output connections from the CPE array and to the routing structure as well as the vertical interconnection to adjacent Block RAM cells.



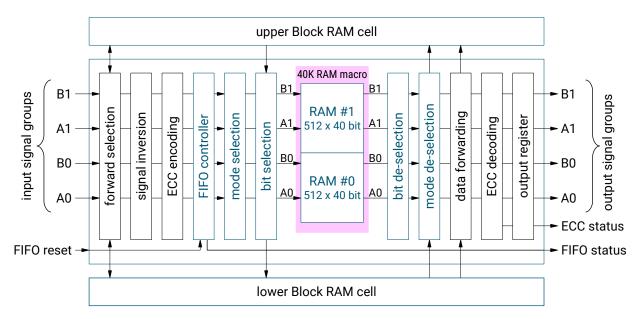


Figure 2.7: High level block diagram of a block RAM cell

The memory inputs can each be fed in from the CPE outputs RAM_01 or RAM_02. Each of the control and address signals CLK, EN, WE and ADDR can be selected from two input connections.

| Signals | Width | Description |
|-------------------------|-------|--------------------------------|
| {a0,a1,b0,b1}_clk{1,2} | 1 | Clock signal |
| {a0,a1,b0,b1}_en{1,2} | 1 | Enable signal |
| {a0,a1,b0,b1}_we{1,2} | 1 | Write enable signal |
| {a0,a1,b0,b1}_addr{1,2} | 16 | Address bus |
| {a0,a1,b0,b1}_di | 20 | Data bus |
| {a0,a1,b0,b1}_bm | 20 | Mask for bit-wise write enable |

Table 2.3: Input signal group

Data output signals and status output signals such as ECC and FIFO flags are connected via the CPE inputs RAM_I1 and RAM_I2 to the Switch Boxes (SBs) of the routing structure.

The entire functionality of the Block RAM is implemented over several layers around the RAM cores. The forward selection part allows a flexible switching between several incoming signals of which one can be selected and forwarded to the next layers. This corresponds to the clock, enable, write enable, address, data and bitmask signals. The forward selection determines whether signals (a) from an adjacent RAM cell, e.g., to allow the building of wider or deeper memories, or (b) from the CPE array via the input signal groups A0, A1, B0 and B1 are routed to the next layers.

In the signal inversion block the clock, enable and write enable signals are individually inverted depending on the configuration.

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The Block RAM provides an internal ECC encoding and decoding layer to protect data against corruption. Depending on the configuration, 8 or 16 bits are required for storage of the parity bits. This feature is therefore only available for data widths of 40 or 80 bits as shown in Tables 2.1 and 2.2. Due to the storage of the parity bits, the actual net data width is 32 or 64 bits. Error correction is implemented using Hamming-code (39,32) with 7 parity bits. It can correct one bit error and detect two bit errors. The error status can be queried via the corresponding output signals. Section 2.4.7 describes the ECC features in more detail.

With the FIFO feature enabled, the internal write and read pointers will be forwarded to the memory macros. The address signals are therefore ignored. Port B is the push while port A is the pop side. The FIFO is configurable to be synchronous or asynchronous. Additional flags indicate the current status, such as empty, full, almost empty, almost full, read error, write error as well as the current FIFO read and write pointers. Moreover, the FIFO controller has a dedicated active low reset signal FIFO_RST_N. Section 2.4.9 describes the FIFO features in more detail.

The mode selection part forwards the incoming signals of ports A0, A1, B0 and B1 to the 8 ports of the memory hard macros according to the selected mode. Sections 2.4.3 and 2.4.4 describe the TDP and SDP modes in more detail.

Each port has an optional output register to improve design performance. If enabled, validity of the output data and ECC status flags get registered and thus delayed by one clock cycle.

2.4.3 TDP Mode

Block RAM in true dual port (TDP) mode supports simultaneous read and write operations and has two independent access ports. Figures 2.8 and 2.9 illustrate the TDP data flow in both 20K and 40K configurations.

Data can be read to or written from both ports at the same time. Read access to one port while writing to the other is also possible. Both ports can have separate clocks and input and output data widths may be different. Thus, the clocks can be synchronous or asynchronous. Both ports have access to the entire memory at any time.

There is no internal conflict handling when accessing the same address at the same time. Such simultaneous accesses can result in data uncertainty and should be avoided.

If split into two independent 20K cells, the maximum data width per port is 20 bits. In the 40K configuration, the maximum data width per port is 40 bits.

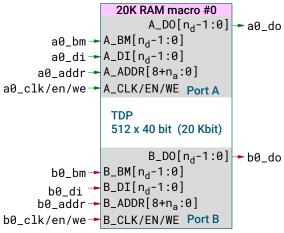
Table 2.4 shows the data and address bus wiring in TDP 20K mode when using half Block RAM #0. Control signals are a0_clk, a0_en and a0_we. The wiring of a0_di also applies to the a0_bm signals. The wiring for the other half Block RAM #1 ports A1 and B1 is equivalent.

Table 2.5 shows the data and address bus wiring in TDP 40K mode when using ports A0 and A1 to form port A. Control signals are a0_clk, a0_en and a0_we. Note that due to the port combining, the maximum data width per port is 40 bits. The wiring of a0_di



Data width: $n_d = 1 ... 20$ Address width: $n_a = 0 ... 5$

Separate values n_d and n_a for ports A and B as well as for data read and write accesses.



Same for RAM #1, where all signals $a0_*$ and $b0_*$ are $a1_*$ and $b1_*$.

Figure 2.8: Internal data flow of DPSRAM in TDP 20K mode

Data width: $n_d = 1 ... 40$ Address width: $n_a = 0 ... 6$

Separate values n_d and n_a for ports A and B as well as for data read and write accesses.

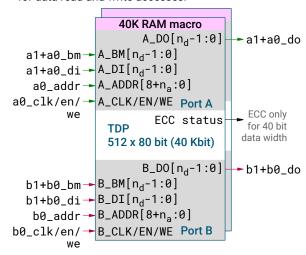


Figure 2.9: Internal data flow of DPSRAM in TDP 40K mode

also applies to the a0_bm signals. The wiring for port B, which is formed by B0 and B1, is equivalent.

2.4.4 SDP Mode

Block RAM in simple dual port (SDP) mode supports simultaneous read and write operations, but has a single output port for read data. By that, data widths can be doubled compared to the TDP mode.

Port A is always the write port, while port B is always the read port. Both write and read

| Width | Depth | Address-in bus ¹ | Data-in bus ¹ | Data-out bus 1 |
|-------|--------|------------------------------|--------------------------|----------------|
| 1 | 16,384 | a0_addr[15:7] o a0_addr[5:1] | a0_di[0] | a0_do[0] |
| 2 | 8,192 | a0_addr[15:7]。a0_addr[5:2] | a0_di[1:0] | a0_do[1:0] |
| 5 | 4,096 | a0_addr[15:7]。a0_addr[5:3] | a0_di[4:0] | a0_do[4:0] |
| 10 | 2,048 | a0_addr[15:7]。a0_addr[5:4] | a0_di[9:0] | a0_do[9:0] |
| 20 | 1,024 | a0_addr[15:7]∘a0_addr[5] | a0_di[19:0] | a0_do[19:0] |

Table 2.4: Pin wiring in TDP 20K mode

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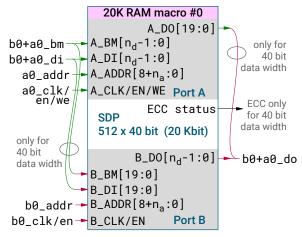
¹ Symbol ∘ is concatenation.

Data width:

Data width: $n_d = 1 ... 20 (1 ... 40 bits)$

Address width: $n_a = 0..5$

Separate values n_d and n_a for ports A and B.



Same for RAM #1, where all signals $a0_*$ and $b0_*$ are $a1_*$ and $b1_*$.

Address width: $n_a = 0...6$ Separate values n_d and n_a for ports A and B. 40K RAM macro b1+b0+ B_D0[39:0] a1+a0_bm A_BM[n_d-1:0] only for b1+b0+ 80 bit A_DI[n_d-1:0] a1+a0_di data width $A_ADDR[8+n_a:0]$ a0_addr A_CLK/EN/WE Port A a0_clk/en/ ECC only we ECC status for 40 bit SDP data width 512 x 80 bit (40 Kbit) only for 80 bit $B_D0[n_d-1:0]$ b1+b0 data width +a1+a0_do B_BM[39:0] B_DI[39:0] b0 addr $B_ADDR[8+n_a:0]$ b0_clk/en → B_CLK/EN

 $n_d = 1 ... 40 (1 ... 80 bits)$

Figure 2.10: Internal data flow of DPSRAM in SDP 20K mode

Figure 2.11: Internal data flow of DPSRAM in SDP 40K mode

ports can have separate clocks. The write port A uses the enable signal {a0, a1}_en and write enable signal {a0, a1}_we for write access and the read port B uses only the enable signal {b0,b1}_en for read access.

Table 2.6 shows the data and address bus wiring in SDP 20K mode. By combining the data buses on ports A0 and B0, the maximum bus width can be doubled compared to the TDP mode. Control signals for the write port A are a0_clk, a0_en and a0_we. Control signals for the read port B are b0_clk and b0_en. The wiring of {a0,b0}_di also applies to the {a0,b0}_bm signals. The wiring for ports A1 and B1 is equivalent.

Table 2.5: Pin wiring in TDP 40K mode

| Width | Depth | Address-in bus | Data-in bus ¹ | Data-out bus ¹ |
|-------|--------|----------------|--------------------------|---------------------------|
| 1 | 32,768 | a0_addr[15:1] | a0_di[0] | a0_do[0] |
| 2 | 16,384 | a0_addr[15:2] | a0_di[1:0] | a0_do[1:0] |
| 5 | 8,192 | a0_addr[15:3] | a0_di[4:0] | a0_do[4:0] |
| 10 | 4,096 | a0_addr[15:4] | a0_di[9:0] | a0_do[9:0] |
| 20 | 2,048 | a0_addr[15:5] | a0_di[19:0] | a0_do[19:0] |
| 40 | 1,024 | a0_addr[15:6] | a1_di[19:0] | a1_do[39:0] |
| | | | ∘a0_di[19:0] | ∘ a0_do[39:0] |

¹ Symbol ∘ is concatenation.



Table 2.7 shows the data and address bus wiring in SDP 40K mode. By combining the data buses on all ports A0, B0, A1 and B1, the maximum bus width can be doubled compared to the TDP mode. Control signals for the write port A are A0_CLK, A0_EN and A0_WE. Control signals for the read port B are b0_clk and b0_en. The wiring of $\{a0, a1, b0, b1\}$ _di also applies to the $\{a0, a1, b0, b1\}$ _bm signals.

2.4.5 Expanding Data Widths and Cascade Mode

The Block RAM allows the coupling of adjacent Block RAMs to build larger or deeper memories by forwarding clock, enable, write enable and address signals. This feature facilitates the routing in the CPE array and the routing structure for the signals mentioned.

The cascade mode extends this feature by forwarding data and bitmask as well. It only allows a data width of 1 bit. Cascading is only possible in the lower direction, as shown in Figure 2.12 on page 30. By that, two adjacent $32K \times 1$ bit Block RAM cells can be combined to form a $64K \times 1$ bit memory. The actual data and bitmask inputs and outputs of the cascade are the data and bitmask inputs and outputs of the upper RAM cell. Prerequisite is that both RAM cells involved are configured in $32K \times 1$ bit TDP mode. Bit 0 of the address bus selects the upper or lower Block RAM cell for the write or read operation.

2.4.6 Memory Mapping and Content Initialization

Each port can access a certain memory area depending on its configuration. The addressing scheme depends on the configuration mode. Words of 5, 10, 20, 40 and 80^2 bits are

 Table 2.6: Pin wiring in SDP 20K mode

| Width | Depth | Address-in bus | Data-in bus ¹ | Data-out bus ¹ |
|-------|-------|--------------------|--------------------------|---------------------------|
| 40 | 512 | {b0,b0}_addr[15:7] | b0_di[19:0] | b0_do[19:0] |
| | | | ∘a0_di[19:0] | ∘ a0_do[19:0] |

¹ Symbol ∘ is concatenation.

Table 2.7: Pin wiring in SDP 40K mode

| Width | Depth | Address-in bus | Data-in bus ¹ | Data-out bus ¹ |
|-------|-------|--------------------|--------------------------|---------------------------|
| 80 | 512 | {b0,a0}_addr[15:7] | b1_di[19:0] | b1_do[19:0] |
| | | | ∘b0_di[19:0] | ∘ b0_do[19:0] |
| | | | ∘a1_di[19:0] | ∘ a1_do[19:0] |
| | | | ∘a0_di[19:0] | ∘ a0_do[19:0] |

¹ Symbol ∘ is concatenation.

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Data width of 80 bits only supported in 40K SDP mode (see Tables 2.1 and 2.2).



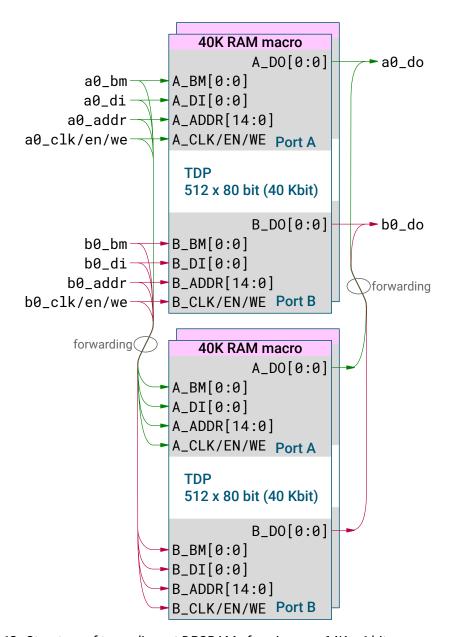


Figure 2.12: Structure of two adjacent DPSRAMs forming one $64K \times 1$ bit memory via cascade feature

distributed equally over all four static random-access memory (SRAM) blocks whereas 1 and 2 bit wide words are arranged so that every 5th bit is not accessible. This leads to a logical mapping of the memory bits as shown in Figure 2.13 on page 31. The scheme shown here can be applied to both SDP and TDP modes in 20K as well as in 40K configurations.

2.4.7 ECC Encoding / Decoding

The Block RAM cell provides an internal ECC encoding and decoding layer to protect data against corruption. If configured, parity bits are generated and checked automatically. Using this feature, the user cannot utilize the all 40 or 80 data bits but must restrict to 32 or 64 bits since the remaining 8 or 16 bits are required for storage of parity bits. This



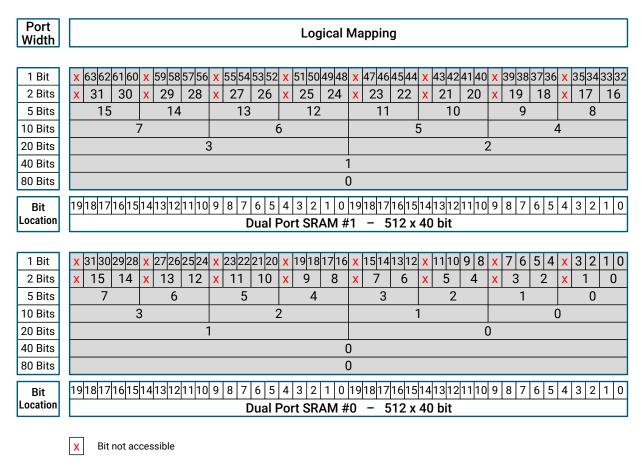


Figure 2.13: Logical data mapping of memory at physical address 0

feature is only available for the following configurations:

- TDP 40K, configured to 40 bits of which user can only use 32 bits
- SDP 40K, configured to 80 bits of which user can only use 64 bits
- SDP 20K, configured to 40 bits of which user can only use 32 bits

In any case the bitmask is ignored, all 32 or 64 bits plus parity are written to memory. For error correction the Hamming-code (39,32) with 7 parity bits is used. It can correct one bit error and detect two bit errors. If one error was detected the ECC single error flag signal will be logic true. If two errors were detected the ECC double error flag will be logic true. There are two dedicated status signals {A,B}_ECC_{1B,2B}_ERR for single and double error flags each, which are utilized in the following way:

- TDP 40K, data width 40 bits: status signal A_ECC_{1B, 2B}_ERR indicate errors at port A while B_ECC_{1B, 2B}_ERR indicate errors at port B
- SDP 40K, data width 80 bits: status signal A_ECC_{1B,2B}_ERR indicate errors while B_ECC_{1B,2B}_ERR are don't care
- SDP 20K, data width 40 bits: status signal A_ECC_{1B,2B}_ERR indicate errors at half Block RAM #0 while B_ECC_{1B,2B}_ERR indicate errors at half Block RAM #1

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2.4.8 RAM Access Modes and Enable

A block RAM cell has three signals to control read and write access. $\{A \mid B\}_EN$ is a global enable signal. It is required to be active during any read or write access. $\{A \mid B\}_WE$ is a global write enable signal that operates in association with the bit-wise write enable vector $\{A \mid B\}_BM$.

Data is only written to the RAM if $\{A \mid B\}_{EN}$, $\{A \mid B\}_{WE}$ and the corresponding bitmask $\{A \mid B\}_{BM}$ are active. Reading of data depends on the selected access mode and the values of $\{A \mid B\}_{WE}$ and $\{A \mid B\}_{BM}$. The address modes are listed in Table 2.8 and 2.9. They show all combinations of $\{A \mid B\}_{EN}$, $\{A \mid B\}_{WE}$ and $\{A \mid B\}_{BM}$ in both modes NO CHANGE and WRITE THROUGH as well as the resulting actions.

Table 2.8: Access combinations in NO CHANGE mode with $\{A \mid B\}_{EN} = 1$ (SDP and TDP)

| {A B}_WE 1 | {A B}_BM[i] | Action on memory and {A B}_D0 |
|------------|-------------|--|
| 0 | 0 | Single read, no update on mem[addr][i] |
| 1 | 0 | Last read, no update on mem[addr][i] |
| 0 | 1 | Single read, no update on mem[addr][i] |
| 1 | 1 | Last read, with update on mem[addr][i] |

¹Only A_WE in SDP mode.

Table 2.9: Access combinations in WRITE THROUGH mode with {A | B}_EN = 1 (TDP only)

| {A B}_WE | {A B}_BM[i] | Action on memory and {A B}_D0 |
|----------|-------------|--|
| 0 | 0 | Single read, no update on mem[addr][i] |
| 1 | 0 | Single read, no update on mem[addr][i] |
| 0 | 1 | Single read, no update on mem[addr][i] |
| 1 | 1 | Write through, with update on mem[addr][i] |

A single read access without any write operation occurs always if the enable signal is active $(A|B)_EN = 1$ and all write enable signals are inactive $(A|B)_BM = 0$, $A|B)_WE = 0$. A single read access is supported in both modes SDP and TDP as shown in Figure 2.14.

All RAM cells can be initialized during configuration and used as read-only memory (ROM). To use the ROM mode the write enable has to be set to zero. The memory mapping for initialization is described in Section 2.4.6.

The NO CHANGE mode is a plain write access with active global enable ($\{A \mid B\}_EN = 1$) and write enable signals ($\{A \mid B\}_BM >= 1$ or $\{A \mid B\}_WE = 1$). The output remains the last read data, i.e. after a single read, and is not affected by a write access. A NO CHANGE access is supported in both modes SDP and TDP as shown in Figure 2.15.

A read first access can be carried out in two clock cycles by first reading a word and then performing a write access in the following cycle.



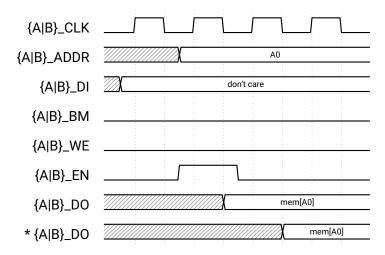


Figure 2.14: Timing diagram of a single read access with optional (*) output register

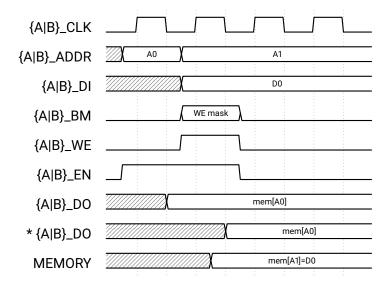


Figure 2.15: Timing diagram of a NO CHANGE access with optional (*) output register

The timing diagram 2.16 illustrates the WRITE THROUGH access, which is a simultaneous write and read access with active global enable ($\{A \mid B\}_{EN} = 1$) and write enable signals ($\{A \mid B\}_{EN} > 1$ or $\{A \mid B\}_{EN} = 1$). New data is written into the memory and simultaneously propagated to the outputs, also known as a transparent write. WRITE THROUGH is only supported in TDP mode.

2.4.9 FIFO Application

Each GateMateTM block RAM cell has an integrated synchronous and asynchronous FIFO controller, allowing usage of a block RAM cell as FIFO memory in the 40K configurations only.

Port B is the write / push port of the FIFO and port A is the read / pop port. In case of syn-

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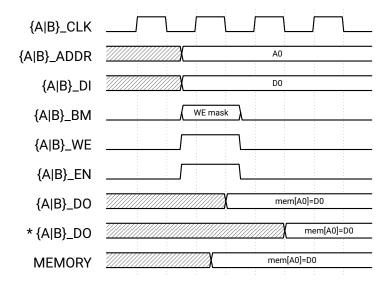


Figure 2.16: Timing diagram of a WRITE THROUGH access with optional (*) output register

chronous FIFO, A_CLK is used as clock for both write / push and read / pop.

Since the FIFO mode is an extension to the TDP / SDP 40K mode, it supports the same bitwidth configurations as shown in Tables 2.5 (page 28) and 2.7. Widths of the input and output buses must be equal.

- TDP 40K, with arbitrary but equal input and output bit width
- SDP 40K, with fixed 80 bit input and output bit width

Data width: $n_d = 1 ... 40 (1 ... 80 bits)$ Address width: $n_a = 0 ... 6$ Separate values n_d and n_a for ports A and B.

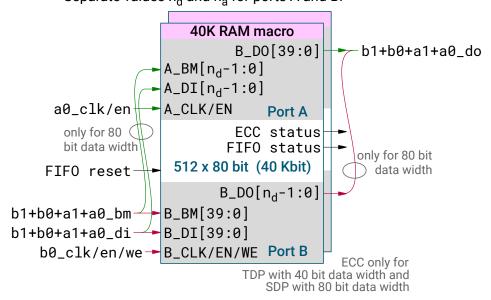


Figure 2.17: Internal data flow of DPSRAM in FIFO mode



In FIFO configuration, the incoming address signals are ignored. Instead, internal read and write pointers with correct alignment according to bitwidth are forwarded to the SRAM macros. Furthermore, there exist additional output signals which are solely used for FIFO monitoring and are described in Table 2.10. The F_ALMOST_FULL_FLAG and F_ALMOST_EMPTY_FLAG give an early warning when the FIFO is approaching its limits. Its offset can be configured using a 13 bit register during configuration or it is set dynamically using the inputs F_ALMOST_FULL_OFFSET and F_ALMOST_EMPTY_OFFSET.

Moreover, the FIFO controller has a dedicated active low reset input signal F_RST_N which is synchronized into clock domain internally.

 Table 2.10: FIFO status flags

| Flag | Width | Description |
|-----------------|-------|--|
| F_FULL | 1 | All entries in the FIFO are filled, is set on the rising edge of the write clock (asynchronous) |
| F_EMPTY | 1 | The FIFO is empty, is set on the rising edge of the read clock (asynchronous) |
| F_ALMOST_FULL | 1 | Almost all entries in the FIFO are filled, is set on the rising edge of the write clock (asynchronous) |
| F_ALMOST_EMPTY | 1 | Almost all entries in FIFO have been read, is set on the rising edge of the read clock (asynchronous) |
| F_READ_ADDRESS | 16 | Current FIFO read pointer |
| F_WRITE_ADDRESS | 16 | Current FIFO write pointer |
| F_RD_ERR | 1 | Is set if FIFO is empty and a read access takes place |
| F_WR_ERR | 1 | Is set if FIFO is full and data is pushed, new data will be lost |

Table 2.11 illustrates the valid FIFO data concatenations for the variable bitwidth data TDP mode. B_EN and B_WE are the write / push enable and A_EN is the read / pop enable signal.

Table 2.11: FIFO 40 bit data concatenations

| Width | Concatenation | |
|-------|---------------|--|
| 40 | B_DI[39:0] | |
| 40 | B_BM[39:0] | |
| 40 | A_D0[39:0] | |
| | 40 40 | |

Table 2.12 illustrates the valid FIFO data concatenations for the 80 bit data SDP mode. B_EN and B_WE are the write / push enable and A_EN is the read / pop enable signal.

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|---|-----|-----|-------------|-----|
| - | | ше | | ле |

Table 2.12: FIFO 80 bit data concatenations

| Function | Width | Concatenation |
|--------------|-------|-------------------------|
| Push data | 80 | B_DI[39:0] o A_DI[39:0] |
| Push bitmask | 80 | B_BM[39:0] o A_BM[39:0] |
| Pop data | 80 | B_D0[39:0] o A_D0[39:0] |

¹ Symbol ∘ is concatenation.

Synchronous FIFO Access

Write / push and read / pop pointers are both registered with the rising clock edge of A_CLK. During the write / push operation, the data word available at $\{A, B\}_DI / \{A, B\}_BM$ is written into the FIFO whenever the B_EN and B_WE signals are active one setup time before the rising clock edge of A_CLK. The write / push operation presents the data word at $\{A0, A1\}_D0$ whenever the A_EN signal is active one setup time the rising clock edge of A_CLK.

The signals empty, full, almost empty, almost full, read and write error are combinatorial computed out of read and write pointer. The error flags are not sticky.

The timing diagram in Figure 2.18 illustrates the writing to an empty synchronous FIFO.

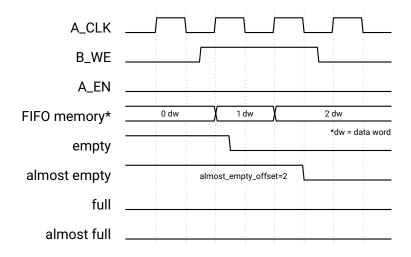


Figure 2.18: Writing to an empty synchronous FIFO



The timing diagram in Figure 2.19 illustrates the writing to an almost full synchronous FIFO.

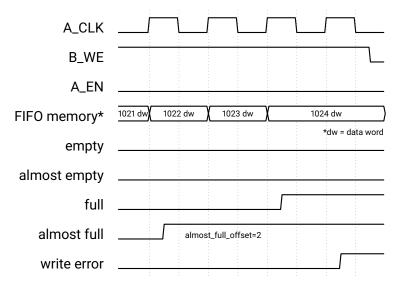


Figure 2.19: Writing to an almost full synchronous FIFO

The timing diagram in Figure 2.20 illustrates the reading from a full synchronous FIFO.

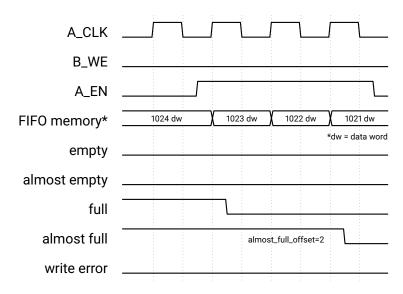


Figure 2.20: Reading from a full synchronous FIFO

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Architecture

The timing diagram in Figure 2.21 illustrates the reading from an almost empty synchronous FIFO.

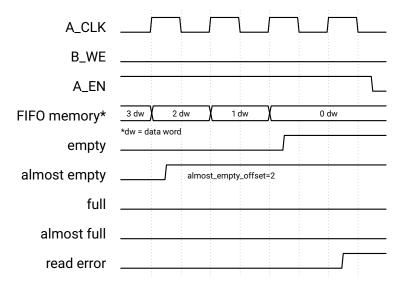


Figure 2.21: Reading from an almost empty synchronous FIFO

Asynchronous FIFO Access

During the write / push operation, the data word available at {A,B}_DI / {A,B}_BM is written into the FIFO whenever the B_EN and B_WE signals are active one setup time before the rising clock edge of B_CLK. The write / push operation presents the data word at {A,B}_DO whenever the A_EN signal is active one setup time the rising clock edge of A_CLK. The read / pop pointer is registered with the read / pop clock A_CLK, the write / push pointer is registered with the write / push clock B_CLK.

For full, empty, almost full, almost empty, read and write error signal generation the read pointer is synchronized into the write clock domain via Gray encoding and 2-stage synchronization, the write pointer is synchronized into the read clock domain via Gray encoding and 2-stage synchronization.

The empty, almost empty and read error signals are combinatorial computed out of the read / pop pointer and the synchronized write / push pointer. By that, the empty, almost empty and read error signals will be always cycle accurate with the read clock without any delay and a read from an empty FIFO can always be prevented.

In Figures 2.22 to 2.25, these signals are highlighted in red relate to the read side of the FIFO since their computation bases on flip-flops driven by the read / pop clock. The full, almost full and write error signals are combinatorial computed out of the write / push pointer and the synchronized read / pop pointer. By that, the full, almost full and write error signals will be always cycle accurate with the write clock without any delay and a write to a full FIFO can always be prevented.

Moreover, the signals highlighted in green are related to the write side of the FIFO since their computation bases on flip-flops driven by the write / push clock.



The timing diagram in Figure 2.22 illustrates the writing to an empty asynchronous FIFO.

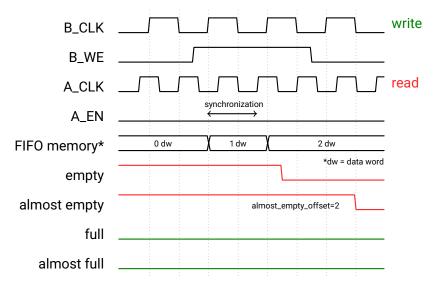


Figure 2.22: Writing to an empty asynchronous FIFO

The timing diagram in Figure 2.23 illustrates the writing to an almost full asynchronous FIFO.

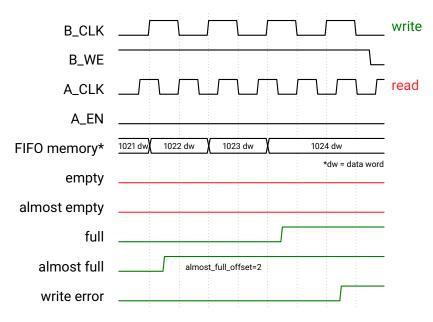


Figure 2.23: Writing to an almost full asynchronous FIFO

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The timing diagram in Figure 2.24 illustrates the reading from a full asynchronous FIFO.

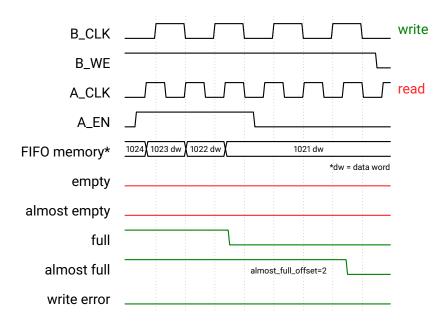


Figure 2.24: Reading from a full asynchronous FIFO

The timing diagram in Figure 2.25 illustrates the reading from a full asynchronous FIFO.

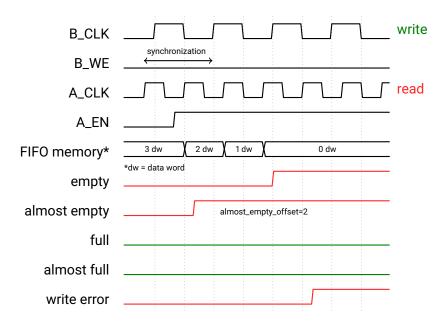


Figure 2.25: Reading from an almost empty asynchronous FIFO



2.5 Clock Generators (PLLs)

Four independent PLL clock generators are available:

- All-digital phase-locked loop (ADPLL) clock generator for versatile FPGA clock generation.
- Clock generation based on a digitally controlled oscillator (DCO) running with a typical frequency tuning range from 1 GHz to 2 GHz.
- Programmable clock frequency dividers for reference clock input, PLL loop divider and core clock outputs, enabling wide output and reference frequency ranges.
- Core clock outputs available at four 90°-spaced phases.
- Fast lock-in by binary frequency search.
- Autonomous free-running oscillator mode for FPGA configuration clock after powerup.

The maximum oscillator frequency depends on the FPGA supply voltage as follows:

```
Low power mode: (VDD_{PLL} = 0.9 \text{ V} \pm 50 \text{ mV}): 1.000 MHz

Economy mode: (VDD_{PLL} = 1.0 \text{ V} \pm 50 \text{ mV}): 2.000 MHz

Speed mode: (VDD_{PLL} = 1.1 \text{ V} \pm 50 \text{ mV}): 2.500 MHz
```

The maximum PLL output frequency also depends on the FPGA supply voltage as follows:

```
Low power mode: (VDD_{PLL} = 0.9 \text{ V} \pm 50 \text{ mV}): 250 MHz
Economy mode: (VDD_{PLL} = 1.0 \text{ V} \pm 50 \text{ mV}): 312.5 MHz
Speed mode: (VDD_{PLL} = 1.1 \text{ V} \pm 50 \text{ mV}): 416.75 MHz
```

There are different reference clock pins selectable individually for each PLL:

- SerDes clock input SER_CLK (pin T12, can also be used as general purpose clock input)
- SPI clock input SPI_CLK (pin N4)
- JTAG clock input JTAG_TCK (pin R3)
- Clock input CLK0 (2nd function of pin N14, 1st function is GPIO IO_SB_A8)
- Clock input CLK1 (2nd function of pin P12, 1st function is GPIO I0_SB_A7)
- Clock input CLK2 (2nd function of pin P14, 1st function is GPIO IO_SB_A6)
- Clock input CLK3 (2nd function of pin R13, 1st function is GPIO IO_SB_A5)

The same reference clock can be used from several PLLs at the same time.

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2.6 Routing Structure

All functional elements of the GateMateTM FPGA are interconnected by the routing structure. This consist of so called *Switch Boxes (SBs)* mainly and is supplemented by additional *Input Multiplexers (IMs)* and *Output Multiplexers (OMs)*. All Switch Boxes are arranged in a matrix $(x, y) = (-1, -1) \dots (162, 130)$ as shown in Figure 2.26.

Architecture

Every second coordinate is populated by Switch Boxes. There are two types of Switch Boxes which differ only in the span they can forward into the routing matrix. Mainly, Switch Boxes connect bidirectional to other Switch Boxes in horizontal and vertical direction. Big Switch Boxes connect six other Switch Boxes in every direction and Small Switch Boxes only two others. Direction change from vertical to horizontal and vice versa

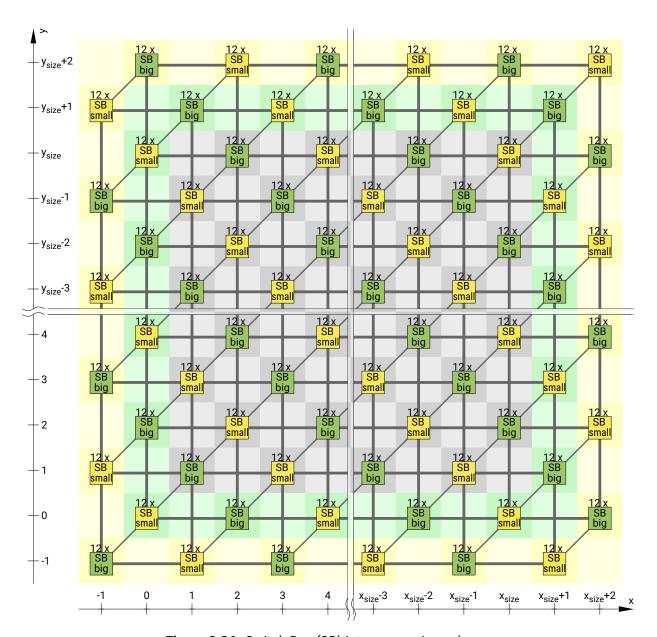
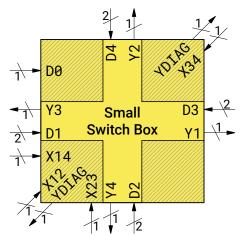


Figure 2.26: Switch Box (SB) interconnection scheme







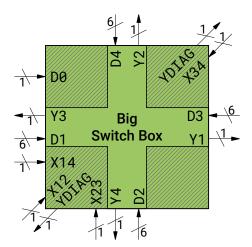


Figure 2.28: Big Switch Box

is possible. From an arbitrary point (x_n, y_m) all coordinates in row y_m or column x_n are reachable.

Furthermore, diagonal neighbors to upper right (x_n+1,y_m+1) and lower left (x_n-1,y_m-1) coordinate can be connected. This allows change to neighbored rows or columns.

Signals are feed into the routing structure either directly from CPE outputs or, for more flexibility, through Output Multiplexers (OMs). GPIO input signals are connected to the Switch Boxes as well.

The Switch Boxes decouple all signals through Input Multiplexers (IMs) to the CPEs.

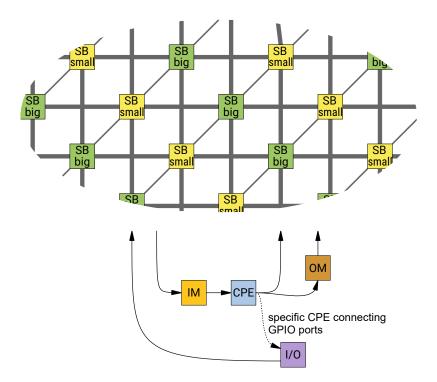


Figure 2.29: CPE connections to the routing structure

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2.7 Power Supply

The GateMateTM FPGA has a single power supply for the chip core and GPIO power supply pins for each GPIO bank. There are some more power pins for dedicated parts of the FPGA:

VDD: Core supply voltage.

VDD_CLK: Supply voltage for the input pins SER_CLK, SER_CLK_N, RST_N and POR_ADJ.

VDD_PLL: Supply pin for PLLs.

VDD_SER: Supply pin for the SerDes module.

VDD_SER_PLL: Supply pin for the SerDes PLL.

VDD_EA, VDD_EB, VDD_NA, VDD_NB, VDD_SA, VDD_SB, VDD_WA, VDD_WB and VDD_WC: Supply pins for GPIO banks.

Core voltage can be chosen to select the application mode:

Low power mode: $VDD = 0.9 V \pm 50 \,\mathrm{mV}$

Economy mode: $VDD = 1.0 V \pm 50 \,\mathrm{mV}$

Speed mode: $VDD = 1.1 V \pm 50 \,\mathrm{mV}$

VDD_PLL has the same core voltage range. VDD_SER and VDD_SER_PLL have a voltage range from $1.0\,V \pm 50\,mV$ to $1.1\,V \pm 50\,mV$. All voltages should be connected to noise filters.

The voltage range of GPIO banks and VDD_CLK can be set from 1.1 V to 2.7 V.

Chapter 3

Workflow and Hardware Setup

3.1 FPGA Workflow

3.1.1 Overview

The workflow from design entry to the GateMateTM FPGA configuration file is shown in Figure 3.1.

Design entry is accomplished using entry tools or any Hardware Description Language (HDL). The Yosys Open SYnthesis Suite (Yosys) (2) is used to perform Register Transfer Level (RTL) synthesis. It has extensive Verilog support. VHDL sources can be synthesized via GHDL (2) through the ghdl-yosys-plugin (2). Other HDLs and tools with Verilog backend can also be used. A guide to the synthesis options of Yosys for the GateMate techlib directory is described in Section 3.1.2.

Synthesis generates a gate-level representation of the design entry in form of a Verilog netlist of architecture-specific primitives. The resulting netlist can be used for post-synthesis simulation with any simulator. The required simulation models are part of the GateMate techlib directory in Yosys.

Furthermore, the netlist is passed to the Place & Route tool for architecture–specific implementation and bitstream generation. A netlist converter generates a generic netlist from the Yosys or legacy netlist. The first steps of Place & Route comprise procedures for speed or area optimization before mapping. After placement and routing, the static timing analysis (STA) might lead to further optimization steps and makes the Place & Route software an iterative process of constraint–driven re–placement and re–routing steps to finally achieve user requirements.

After successful placement and routing, a Verilog netlist with the associated Standard Delay Format (SDF) for timing-based post-implementation simulation are generated.

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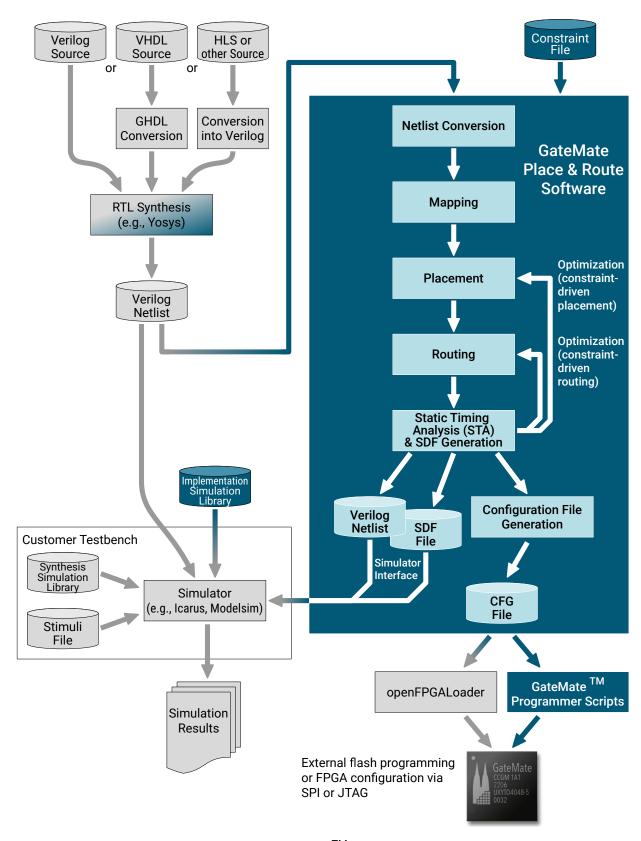


Figure 3.1: GateMateTM FPGA workflow

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Simulation of the Verilog netlist requires a library of simulation models provided by Cologne Chip. Again, any simulator can be used.

The resulting configuration bitfile can either be written into a flash memory or directly to the FPGA configuration controller using it's JTAG or SPI interfaces. openFPGALoader

↑ has full support for GateMateTM FPGA configuration. Alternatively, Cologne Chip offers customizable scripts for configuration. A guide to programming external flash and FPGA configuration using openFPGALoader is described in Section 3.1.4.

3.1.2 Synthesis

This section describes the architecture-specific options of the synth_gatemate pass in Yosys to run synthesis.

-top <module>

Uses the specified module as top-level module. In general, Yosys autodetects the top-level module within the set of input files.

-noflatten

Omits flattening of the design before synthesis. Yosys automatically flattens the netlist for efficiency. This option gives per-module synthesis statistics that can be used to discover modules in need for optimization. Note that the Cologne Chip Place & Route accepts flattened netlists only.

The following commands disable architecture–specific cells. In order to be able to use the full functionality, none of these options should be set. These options generally slow down design performance and increase area usage.

-nobram

Omits using CC_BRAM_20K or CC_BRAM_40K block RAM cells in the output netlist, forcing Yosys to build memories out of registers.

-noaddf

Omits using CC_ADDF full adder cells in the output netlist.

-nomult

Omits using CC_MULT multiplier cells in the output netlist.

-nomx8, -nomx4

Omits using CC_MX{8,4} multiplexer cells in the output netlist.

-noiopad

Disables I/O buffer insertion (useful for hierarchical or out-of-context flows).

-noclkbuf

Disables automatic clock buffer CC_BUFG insertion.

Moreover, following synthesis-related options may be used to improve efficiency in terms of area and speed.

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-luttree

This option is recommended as it enables LUT-tree mapping to CC_L2T4 and CC_L2T5 cells. Mapping to LUT-trees is omitted if this parameter is not specified. Yosys then defaults to traditional LUT mapping that results in less efficient implementation results during place and route.

-retime

This option makes LUT mapping DFF-aware. It is able to remove or move registers to balance logic. Design performance benefits from that option.

In addition, there are options to call Yosys backends to write the netlist to a file.

-vlog

Writes the design to the specified Verilog file. It is used as simulation netlist or input for the Cologne Chip Place & Route. Writing of an output file is omitted if this parameter is not specified.

-json

Writes the design to the specified JSON file. It is used as input for Place & Route in nextpnr (future feature). Writing of an output file is omitted if this parameter is not specified.

3.1.3 Implementation

Place & Route Options

This section describes the available options of the Cologne Chip Place & Route to run implementation and bitstream generation. In general, the tool accepts Verilog netlists of architecture-specific primitives as generated in the synth_gatemate pass in Yosys. IO planning is handled with CCF constraint files.

Boolean options can be set with + and reset with - (++ or -- if using long option). Alternatively, $1/\theta$, on / off or true / false can be used for set and reset of an option as suffix. Option setting by suffix has priority over setting by +/-. E.g. "-X on " means option X is set.

-h, --help

Displays help information and exits.

-i <arg>, --input <arg>

Netlist input path and file name.

-lib <arg>, --lib <arg>

Specifies the library format used in the input netlist. Available libraries are {auto, ccag, xise, xvivado, yvivado}.

-o <arg>, --output <arg>

Output file name.

-ccf <arg>, --ccf <arg>

CCF constraints input path and file name.



-v, --verbose

Verbose mode.

-om <arg>, --fpga_mode <arg>

Operation mode {1:lowpower, 2:economy, 3:speed} (default: 3).

-tm <arg>, --time_mode <arg>

Timing mode {1:best, 2:typical, 3:worst} (default: 3).

The following commands control clock and optimization parameters.

-sf <arg>, --skew_factor <arg>

Skew violation factor of data path delay (default: 0.8).

+/-s, ++/--skew

Enable clock skew routing iteration (default: on).

+/-cCP, ++/--clk_CP

Use CP-lines for CPE inputs CLK and EN (default: on).

+/-gCP, ++/--gate_CP

Use CP-lines to build large gates using cascaded CPEs (default: on).

+/-cgb, ++/--clk_gl_bot

Force clocks over CP-lines from bottom edge (default: off).

+/-cgbc, ++/--gl_bot_chain

Force chaining instead of mesh in bottom edge (default: off).

+/-AF, ++/--AF

Combine adder and flip-flop functions in one CPE (default: off).

+/-dC, ++/--dual_CPE

Combine 2 gates into one CPE (default: on).

+/-sp, ++/--speed

Speed constraint (default: off).

+/-dl, ++/--del_latch

Delete latches with clamped G input (default: on).

+/-df, ++/--del_FF

Delete flip-flops with clamped set / reset inputs (default: on).

-pb <arg>, --place_box X<x1>Y<y1>X<x2>Y<y2>

Restricts the usable area in the CPE array, where $\{x1, x2\}$ in [1..160] and $\{y1, y2\}$ in [1..128].

The following commands control reports and output file parameters.

+/-ics, ++/--icarus_sdf

Generate Icarus Verilog compatible SDF (default: off).

+/-tp <arg>, ++/--time_pathes <arg>

Number of pathes in the timing report (default: 0).

+/-cdf, ++/--cdf

Write CDF file (default: on).

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+/-pin, ++/--pin

Write PIN file (default: on).

+/-plc, ++/--plc

Write PLACE file (default: on).

+/-crf, ++/--crf

Generate cross reference file (default: off).

The following commands control global I/O-related parameters.

+/-CPE_in, ++/--CPE_inpin

Locate CPE next to FPGA input pin (default: off).

+/-CPE_out, ++/--CPE_outpin

Locate CPE next to FPGA output pin (default: off).

+/-uCIO, ++/--use_CFG_IOs

Use configuration I/Os as user GPIOs (default: off).

The following commands control configuration related parameters.

+/-pr, ++/--pwr_red

Reduce active power by setting unused Switch Box nodes inactive (default: on).

+/-m_spi <arg>, ++/--SPI_m_mode <arg>

SPI master settings {00:disable, 11:single, 12:dual, 14:quad} (default: 00).

+/-s_spi <arg>, ++/--SPI_s_mode <arg>

SPI slave settings {0:disable, 1:single, 4:quad} (default: 0).

CCF Contraint File Format

Entries in the CCF contraints file have the following format:

```
<pin-direction> "<pin-name>" Loc = "<pin-location>" | <opt.-constraints>;
```

Additional constraints can be appended with the pipe symbol.

SCHMITT_TRIGGER={*true*, *false*}

Enables or disables Schmitt-trigger (hysteresis) option.

PULLUP={true,false}

Enables or disables I/O pull-up resistor of nominal 50 k Ω .

PULLDOWN={true,false}

Enables or disables I/O pull-down resistor of nominal 50 k Ω .

KEEPER={*true*, *false*}

Enables or disables I/O keeper option.

SLEW={slow,fast}

Sets slew rate to slow or fast.

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DRIVE={3,6,9,12}

Sets output driver strength to 3 mA.. 12 mA.

DELAY_IBF={0..15}

Adds an additional delay of n times the nominal 50 ps to the output signal.

DELAY_OBF={0..15}

Adds an additional delay of n times the nominal 50 ps to the input signal.

FF_OBF={true,false}

Enables or disables placing of flip-flops in input buffer, if possible.

FF_OBF={true,false}

Enables or disables placing of flip-flops in output buffer, if possible.

Global I/O constraints can be set with the default_GPIO statement. It can be overwritten by individual settings for specific GPIOs .

default_GPIO | DRIVE=3; # sets all output strengths to 3mA, unless
 overwritten

3.1.4 Configuration

This section describes the options to configure the CCGM1A1 and access external flash memory with openFPGALoader of for the following boards and cables:

- GateMate[™] FPGA Evaluation Board
- GateMate[™] FPGA Programmer

Supported configuration files are bitfiles *.bit and it's ASCII equivalents *.cfg as generated from Cologne Chip Place & Route. The most useful options are listed as follows. Examples of how to use the tool are given below.

-b, --board <arg>

Specifies board and interface: '-b gatemate_evb_jtag' or '-b gatemate_evb_spi'.

-c, --cable <arg>

Specifies programmer cable: '-b gatemate_pgm'.

--freq <arg>

Use the specified frequency to shift the bitstream in Hz. Append 'k' to the argument for frequency in kilohertz, or 'M' for frequency in megahertz, e.g. '--freq 10M' (default: 6M).

-f, --write-flash

Writes the bitstream to an external flash memory.

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JTAG Configuration

This mode performs an active hardware reset and writes the configuration into the FPGA latches via JTAG. The configuration mode pins CFG_MD[3:0] must be set to $0 \times C$ (JTAG mode).

Program using the evaluation board ☑:

```
$ openFPGALoader -b gatemate_evb_jtag <bitfile>.{cfg,bit}
```

Program using the programmer board ☑:

```
$ openFPGALoader -c gatemate_pgm <bitfile>.cfg.bit
```

SPI Configuration

Performs an active hardware reset and writes the configuration into the FPGA latches via SPI. The configuration mode pins CFG_MD[3:0] must be set to 0x 4 (SPI passive mode).

Program using the evaluation board ☑:

```
$ openFPGALoader -b gatemate_evb_spi <bitfile>.{cfg,bit}
```

Program using the programmer board ☑:

```
$ openFPGALoader -b gatemate_pgm_spi <bitfile>.{cfg,bit}
```

JTAG Flash Access

It is possible to access external flashes via the internal JTAG-SPI bypass. The configuration mode pins CFG_MD[3:0] must be set to 0x C (JTAG mode). Note that the FPGA will not start automatically.

Write to flash using the evaluation board \square :

```
$ openFPGALoader -b gatemate_evb_jtag <bitfile>.{cfg,bit}
```

Program using the programmer board \square :

```
$ openFPGALoader -c gatemate_pgm -f <bitfile>.{cfg,bit}
```

The 'offset' parameter can be used to store data at any point in the flash, e.g.:

```
$ openFPGALoader -b gatemate_evb_jtag -o <offset> <bitfile>.{cfg,bit}
```

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SPI Flash Access

If the programming device and the FPGA share the same SPI signals, it is possible to hold the FPGA in reset and write data to the flash. The configuration mode can be set as desired. If the FPGA should start from the external memory after reset, the configuration mode pins CFG_MD[3:0] must be set to 0×0 (SPI active mode).

Write to flash using the evaluation board \square :

```
$ openFPGALoader -b gatemate_evb_spi -f <bitfile>.{cfg,bit}
```

Program using the programmer board ♂:

```
$ openFPGALoader -b gatemate_pgm_spi -f <bitfile>.{cfg,bit}
```

The 'offset' parameter can be used to store data at any point in the flash, e.g.:

```
$ openFPGALoader -b gatemate_evb_spi -o <offset> <bitfile>.{cfg,bit}
```

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3.2 Hardware Setup

3.2.1 Power-on Reset

The GateMateTM FPGA has a reset pin RST_N with Schmitt-trigger characteristic and internal pull-up resistor. Signal polarity is active low.

The power-on reset (POR) module ensures a safe reset as soon as core voltage VDD and VDD_CLK supply voltages are stable. Figure 3.2 shows the POR block diagram. The POR module has the following features:

- Safe reset generation after stable VDD and VDD_CLK voltages.
- Voltage drop detection for VDD and VDD_CLK voltages.
- Adjustable VDD_CLK voltage threshold.
- No restrictions concerning order of voltage switch-on.
- Temperature compensated voltage reference.

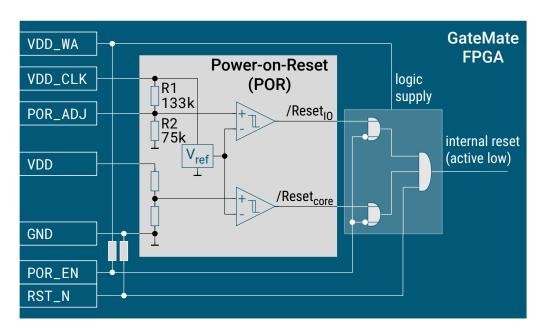


Figure 3.2: Power-on reset (POR) module block diagram

The POR must be enabled with POR_EN signal:

- **0:** Reset state depends only on the RST_N signal.
- 1: FPGA changes from reset to operation state when RST_N is 1 and POR indicates VDD and VDD_CLK voltages are stable.

POR_EN has an internal pull-down resistor and can be left open if not used.

Figure 3.3 shows an exemplary supply voltage curve to explain the operation behavior of the POR reset output signals. Please see the electrical specification given in Table 4.6 on page 76 for exact threshold values in different operating cases.



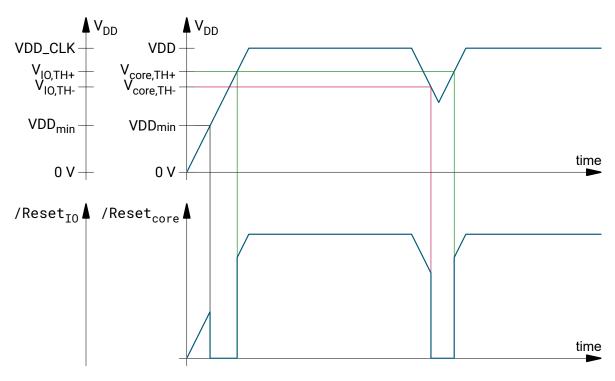


Figure 3.3: Threshold principles of POR

3.2.2 FPGA reset using the POR module

Using the POR module, in many cases no external components are required to ensure a safe reset of the GateMate FPGA. Figure 3.4 shows how to connect the reset pins in this case:

- VDD_WA and VDD_CLK must be connected to 1.1.. 2.7 V supply (might be different).
- POR_EN has to be connected to VDD_WA or it can be left open due to the internal pullup resistor.
- Pin RST_N must be connected to VDD_CLK.
- In normal operation, POR_ADJ should be left open. The optional voltage divider R3a and R3b is only used, if POR adjustment is required. This depends on the VDD_CLK level (see explanation below).

POR adjustment:

- With VDD_CLK in the range 1.8..2.7V (normal operation), POR_ADJ should be left open.
- R3b will increase the threshold level. Typically, this is not necessary within the specified VDD_CLK supply range. Nevertheless, reset state is permanently set with R3b $\leq 100\,k\Omega.$
- R3a will decrease the threshold level. This is only necessary when VDD_CLK $< 1.8\,V$ to avoid a permanent reset state. There will be no reset condition when R3a $\leq 100\,k\Omega$.

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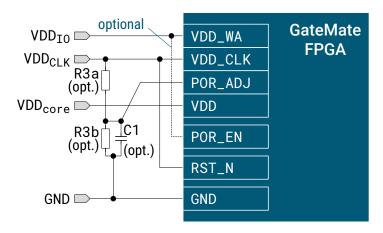


Figure 3.4: FPGA reset using the POR module

• For very low VDD_CLK voltages only a dynamic reset generation by means of R3a and C1 circuitry is possible. POR_ADJ is temporarily kept at ground level by C1. After charging C1 via R3a, the reset is released. The reset time can be approximated by

$$t_{reset} = \frac{\text{R3a} \cdot 75 \, \text{k}\Omega}{\text{R3a} + 75 \, \text{k}\Omega} \cdot \text{C1} \cdot ln \left(\frac{\text{VDD_CLK}}{\text{VDD_CLK} - \frac{0.45 \, \text{V}}{75 \, \text{k}\Omega} \cdot (75 \, \text{k}\Omega + \frac{\text{R3a} \cdot 133 \, \text{k}\Omega}{\text{R3a} + 133 \, \text{k}\Omega})} \right)$$

For R3a $< 10 \, k\Omega$ this can be simplified to

$$t_{reset} pprox extsf{R3a} \cdot extsf{C1} \cdot ln\left(rac{ extsf{VDD_CLK}}{ extsf{VDD_CLK} - 0.45\, ext{V}}
ight)$$

The reset time should be adjusted to the slope time of the VDD_CLK ramp-up.

3.2.3 FPGA reset without POR module

If the POR module is not to be used (see Figure 3.5), the following settings are required:

- VDD_WA and VDD_CLK must be connected to 1.1.. 2.7 V supply (might be different).
- POR_EN has to be connected to GND.
- POR_ADJ can be left open.
- Pin RST_N must be connected to a logic or RC circuit to ensure a rising edge after stable power supply.



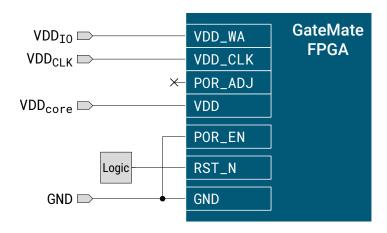


Figure 3.5: FPGA reset driven by an external logic

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3.3 Configuration Procedure

3.3.1 Configuration Modes

The GateMateTM FPGA can be configured from four different sources:

- 1. The configuration process is controlled by the FPGA itself where it acts in SPI active mode, e.g., after reset. Configuration data is read from an external flash memory.
- 2. A processor unit operating as SPI in active mode feeds the configuration data to the FPGA which acts in SPI passive mode.
- 3. The JTAG interface of the FPGA connects to a JTAG test & programming adapter.
- 4. User configured logic of the FPGA can feed configuration data to the FPGA itself.

With the rising edge of the reset signal the configuration mode setup at pins CFG_MD[3:0] gets captured as shown in Table 3.1. These pins must always be connected to either GND or VDD_WA.

Table 3.1: Configuration mode setup

| CFG_MD[3:0]* | | Configuration mode | |
|--------------|---------|--------------------|----------------------|
| 0 x 0 | 0b 0000 | SPI Active Mode | CPOL = 0, $CPHA = 0$ |
| 0x1 | 0b 0001 | SPI Active Mode | CPOL = 0, CPHA = 1 |
| 0x2 | 0b 0010 | SPI Active Mode | CPOL = 1, CPHA = 0 |
| 0x3 | 0b 0011 | SPI Active Mode | CPOL = 1, CPHA = 1 |
| 0x4 | 0b 0100 | SPI Passive Mode | CPOL = 0, $CPHA = 0$ |
| 0x 5 | 0b 0101 | SPI Passive Mode | CPOL = 0, CPHA = 1 |
| 0x6 | 0b 0110 | SPI Passive Mode | CPOL = 1, CPHA = 0 |
| 0x7 | 0b 0111 | SPI Passive Mode | CPOL = 1, CPHA = 1 |
| 0 x C | 0b 1100 | JTAG | |
| | | | |

^{*} Modes not mentioned in the list may not be selected and lead to a malfunction of the device.



3.3.2 Configuration Signals

Table 3.2: Configuration signal bank

| Pin | Signal name | Reset category | I/O mode | I/O characteristic | Description |
|-----|----------------|----------------|-------------|---|--------------------------------|
| R5 | CFG_MD0 | 4 | I | | Configuration mode bit 0 |
| T5 | CFG_MD1 | 4 | I | | Configuration mode bit 1 |
| U4 | CFG_MD2 | 4 | I | | Configuration mode bit 2 |
| ۷4 | CFG_MD3 | 4 | I | | Configuration mode bit 3 |
| U1 | POR_EN | 2 | I | pull-down | Enable power-on reset |
| V3 | CFG_DONE | 2 | 0 | pull-down, low, driver strength 12 mA | Configuration done signal |
| V2 | CFG_FAILED_N | 2 | I/O | pull-up, high, open drain, driver strength 12 mA | Configuration failed signal |
| N3 | SPI_CS_N | 3 | I, I/O | pull-up, driver strength 12 mA | Configuration SPI chip select |
| N4 | SPI_CLK | 3 | I, I/O | driver strength 12 mA | Configuration SPI clock |
| P2 | SPI_D0 | 3 | I, I/O | driver strength 12 mA | Configuration SPI data bit 0 |
| P1 | SPI_D1 | 4 | I | | Configuration SPI data bit 1 |
| R2 | SPI_D2 | 4 | I | | Configuration SPI data bit 2 |
| R1 | SPI_D3 | 4 | I | | Configuration SPI data bit 3 |
| R4 | SPI_FWD | 2 | 0 | low, driver strength 12 mA | Configuration SPI data forward |
| T3 | JTAG_TMS | 4 | I | | JTAG test mode select |
| R3 | JTAG_TCK | 4 | I | | Configuration JTAG clock |
| T2 | JTAG_TDI | 4 | I | | JTAG data input |
| U2 | JTAG_TD0 | 2 | 0 | low, driver strength 12 mA | JTAG data output |

Reset categories:

- 0: No reset (supply or analog input pin)
 1: Pin disabled, high-z
 2: Pin characteristic already during reset state
- 3: Pin characteristic depends on the configuration mode (SPI master: I/O, else: input)
- 4: Input pin

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3.3.3 SPI Configuration

The SPI bus of GateMateTM FPGA can be used to load the configuration either in SPI active or passive mode. Both modes use the same pins. Typically, a flash memory is connected to the SPI bus to provide the configuration data. Figure 3.6 shows a typical circuitry which uses only single-I/O or dual-I/O mode. The flash signals I/O_2 and I/O_3 can have further functions depending on the used device and should have pull-up resistors in most cases.

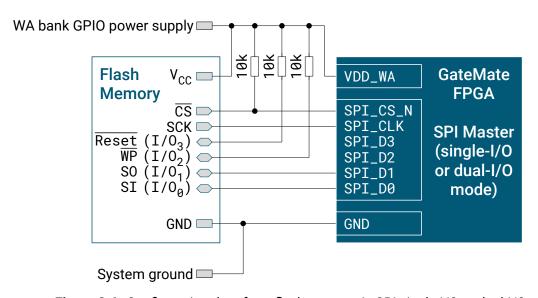


Figure 3.6: Configuration data from flash memory in SPI single-I/O or dual-I/O mode

When SPI quad-I/O mode is used, Figure 3.7 shows the typical circuitry. Now, all data lines are connected and no pull-up resistors are required. Depending on the used flash device, pull-up resistors are recommended at I/O_2 and I/O_3 signals.

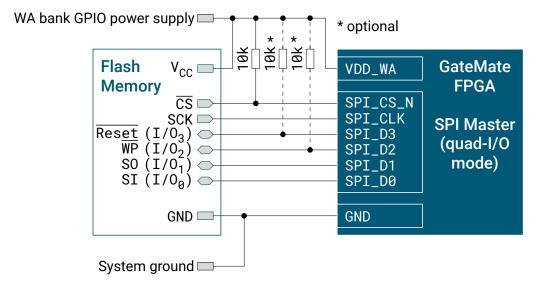


Figure 3.7: Configuration data from flash memory in SPI quad-I/O mode



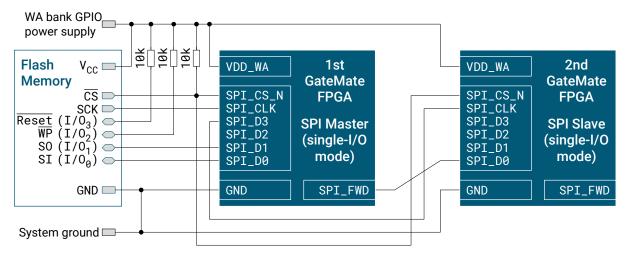


Figure 3.8: Configuration data stream from a single flash memory

Finally, Figure 3.8 shows two GateMateTM FPGAs using the same SPI configuration data source. This is done using the SPI forward function. Only SPI single-I/O mode can be used in this case. In a multi-chip setup multiple FPGAs are configured in a chain.

The GateMateTM FPGA is able to load it's configuration automatically after reset. No external clock is required. When SPI active Mode is set up, the rising edge of RST_N starts reading the configuration data from the flash memory. The internal clock needs no external reference clock. If an external reference clock is available, the configuration stream can set up a phase-locked loop (PLL) to any configuration clock frequency.

When operating in SPI active mode, error detection and correction is done automatically. In this case a short CFG_FAILED_N pulse is given and the failed configuration sequence will be re-read.

When operating in SPI passive mode, the configuration controller can only react on the incoming data stream while the external device in SPI active mode is in control over the bus.

The signals CFG_DONE and CFG_FAILED_N indicate the end of the configuration process as described in Table 3.3.

| CFG_DONE | CFG_FAILED_N | Description |
|----------|--------------|--|
| 0 | 0 * | Invalid state |
| 0 | 1 | Configuration procedure is still in progress |
| 1 | 0 * | Unable to load configuration. Data stream might be invalid |
| 1 | 1 ** | Configuration successful |

Table 3.3: Configuration process state

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^{*} Only long CFG_FAILED_N pulses. Short pulses have no significance.

^{**} CFG_DONE might not be retrievable in case the configuration bank is set to user mode.



CFG_FAILED_N requires a pull-up resistor. If multiple FPGAs are configured from a single flash memory, all CFG_FAILED_N have to be connected as shown in Figure 3.9.

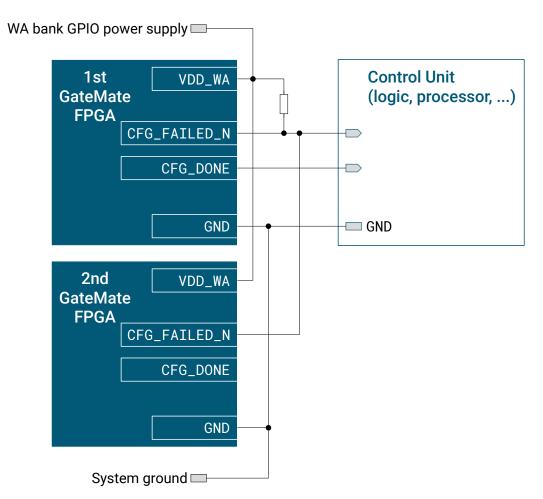


Figure 3.9: Connection of CFG_DONE and CFG_FAILED_N signals in multi-FPGA applications with a single flash memory



3.4 JTAG Interface

3.4.1 JTAG overview

The GateMateTM FPGA configuration bank provides a standard IEEE 1149.1–2001 compliant Test Access Point (TAP) that can be used for the following functions:

- Load configuration via JTAG¹
- Full access to SPI interface using JTAG-SPI bypass
- · Utilities to access external SPI data flashes
- Boundary-Scan Testability: SAMPLE / PRELOAD and EXTEST
- Access to supplementary internal registers

Figure 3.10 illustrates the typical wiring between a single FPGA and a JTAG host controller. By connecting devices via the data input and output signals it is possible to chain multiple TAPs in a serial configuration. The operating range of the supply voltage on the configuration bank is shown in Table 4.3. The JTAG interface is always available after global reset. It will no longer be available once the configuration bank is switched to user I/O after configuration.

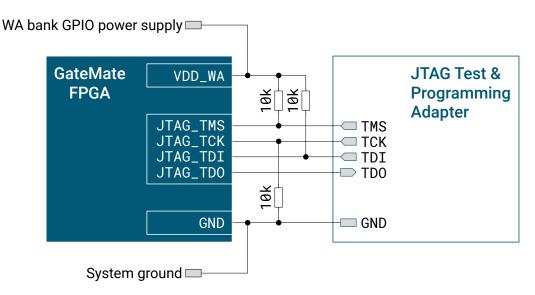


Figure 3.10: JTAG connection scheme

Four signals support the TAP according to the IEEE 1149.1-2001 requirements:

Test Mode Select (TMS) controls the TAP controller state machine. The signal is sampled on the rising edge of TCK.

Test Clock (TCK) provides a clock signal. TMS is sampled on the rising edge of TCK. Input data on TDI is shifted into the instruction (IR) or data (DR) registers on the rising edge of TCK. Output data on TDO is shifted out on the falling edge of TCK.

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See Section 3.3.1 for more ways to load the FPGA configuration.



Test Data Input (TDI) is the serial input to all JTAG instruction (IR) and data (DR) registers depending on the sequence previously applied at TMS.

Test Data Output (TDO) is the serial output for all JTAG instruction (IR) and data (DR) registers depending on the sequence previously applied at TMS.

3.4.2 JTAG Usage

The TMS signal is evaluated on the rising edge of TCK. Its value decides the next state into which the finite-state machine (FSM) changes. The FSM states are shown in Figure 3.11.

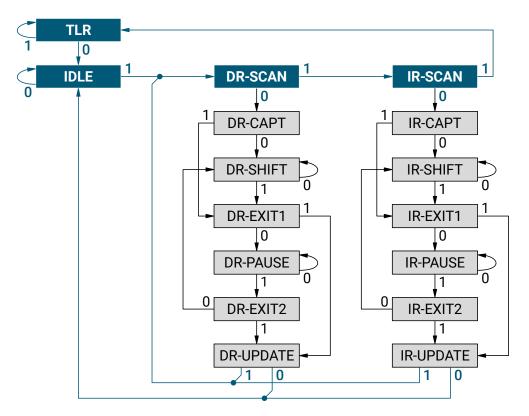


Figure 3.11: Finite-state machine of the JTAG interface

The typical procedure is to first load the instruction and then write or read the data associated with this instruction. The JTAG host controller must drive the signals TCK, TMS and TDI in the according way as illustrated shown in Figures 3.12 and 3.13. The instruction register (IR) size is 6 bits. Instructions have to be shifted into the JTAG TAP with least significant bit (LSB) first.

3.4.3 Common JTAG Instructions

According to IEEE 1149.1-2001, the IDCODE register is optional and thus only contains a placeholder value.



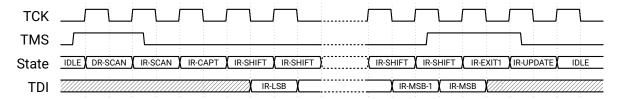


Figure 3.12: JTAG instruction shift NEW COMMAND

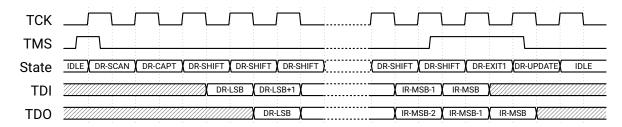


Figure 3.13: JTAG data shift

The bypass mode connects the JTAG TDI and TDO lines via a single-bit pass-through register and allows the testing of other devices in a JTAG chain. In bypass mode, the TDI input is delayed by one clock cycle before outputting to TDO.

Instruction: 0x 3F JTAG_BYPASS Shift width: 1 bit

Configure JTAG bypass mode. The bypass register is set to zero when the TAP controller is in the CAPTURE-DR state.

Shift-in bits: -

Shift-out bits: - Input bit pattern delayed by one clock cycle.

3.4.4 JTAG Configuration

The JTAG interface can be used to configure the FPGA as well. The configuration stream must have a length of a multiple of 8 bits. The JTAG TAP automatically combines every 8 received bits to a single byte and forwards it to the configuration processing block. JTAG configuration works independently of the configuration mode pins CFG_MD[3:0]. However, in order to avoid conflicts, the pins should be set to 0x C. Further information on the configuration modes can be found in Section 3.3.1. The configuration byte stream is in big endian while the bytes are in little endian. If the configuration bank is not switched to user I/O after configuration, the status can be read as usual using the CFG_DONE and CFG_FAILED_N pins.

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| Instruction: | 0x 06 | JTAG_CONFIGURE | Shift width: | M · 8 bits |
|-----------------|---------|--|------------------|------------|
| | | Configure the FPGA with a cobytes. | onfiguration str | ream of M |
| Shift-in bits: | M·[7:0] | The configuration byte stream is in big endian while the bytes are in little endian. | | |
| Shift-out bits: | M·[7:0] | Don't care | | |

3.4.5 Access to SPI Bus

The SPI bus can be accessed directly using the JTAG interface. This way, bitstreams may be written to an external data flash without having to access the bus with additional hardware. There are two ways of acting on the SPI bus via the JTAG interface:

- Full access to SPI interface using JTAG-SPI bypass
- Utilities to access external SPI data flashes

Figure 3.14 illustrates the wiring between a single FPGA connected to an external SPI component and a JTAG host controller.

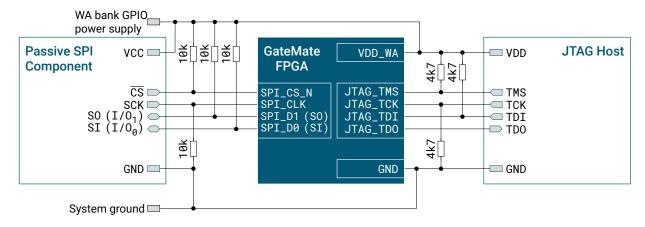


Figure 3.14: JTAG-SPI bypass connection scheme

In active JTAG-SPI bypass mode all JTAG signals JTAG_TCK, JTAG_TDI and JTAG_TDO are directly connected to the SPI pins. Due to the direct connection of JTAG_TCK and SPI_CLK, the clock frequency on the SPI bus is the same as that of the JTAG clock. Before accessing the SPI bus via active bypass it must be ensured that the SPI bus is not busy, e.g., by checking the JTAG_GET_SPI_BUSY command. There is no restriction on the length of a SPI transfer. The SPI bypass mode works for all four SPI modes (CPOL, CPHA), but only in single-IO mode as set via the SPI configuration mode pins CFG_MD[1:0] described in Table 3.1.

With each DR-shift one bit at JTAG_TDI is shifted into the JTAG TAP and directly forwarded to SPI_D0 output. Simultaneously, one bit is shifted into SPI_D1 input. The bit

Workflow and Hardware Setup



will be available on the JTAG output JTAG_TDO at the next falling edge of JTAG_TCK. There must be one more DR-shift cycle than bits to transmit. The last bit shifted into the TAP will not be shifted to the external SPI device and the very first bit shifted out of the TAP is an invalid bit.

| Instruction: | 0x 05 | JTAG_SPI_BYPASS | Shift width: | N bits |
|-----------------|-------|---|--------------|--------|
| | | Active access to SPI bus v | via JTAG. | |
| Shift-in bits: | _ | Data to be shifted into external SPI device | | |
| Shift-out bits: | - | Data to be shifted from external SPI device | | |

Figure 3.15 illustrates the function of the active JTAG-SPI bypass in all four available SPI single-IO modes.

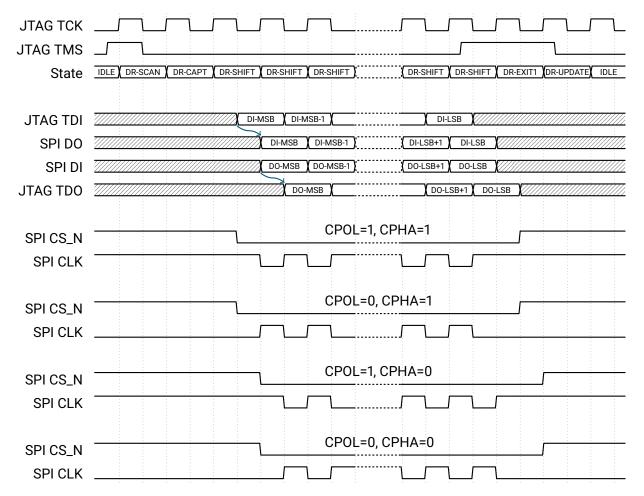


Figure 3.15: Timing diagram of the JTAG-SPI bypass mode.

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3.4.6 Access to SPI data flash

The JTAG_SPI_ACCESS provides access to external SPI data flashes with a conventional command structure, in which command, mode, address and bidirectional data bits can be exchanged. In order to support a wide range of SPI data flashes, all command fields can be adjusted. First, the instructions have to be shifted into the JTAG TAP register with LSB first. The actual SPI transfer start as soon as the DR-UPDATE state in JTAG FSM was executed. In contrast to the JTAG-SPI bypass mode, the SPI clock rate is determined by the clock frequency of the internal oscillator. Access to external SPI data flashes works for all four SPI modes (CPOL, CPHA), but only in single-IO mode. The mode is again indicated by the configuration mode pins CFG_MD[1:0] as described in Table 3.1. Setting CFG_MD2 to one ensures the controller to be in SPI active mode.

The JTAG_SPI_ACCESS command allows transmissions of at most 32 TX data bits. The number of TX bits must be specified and TX words must be set to 1. Moreover, up to 32 bits of data can be received via the JTAG_GET_SPI_RXDATA command after execution of JTAG_SPI_ACCESS with the corresponding read command and number of bits to be received. The RX data flag is only valid if the read command was previously executed.

In order to transfer more than 32 bits, the JTAG TAP contains a register file of 256 bytes that can be filled via the JTAG command JTAG_FLASH_PAGE_PREP before the execution of an JTAG_SPI_ACCESS with a number of TX data word greater than 1. The total number of bits to be transmitted from the register file is the product of TX data bits times TX data words. The internal file register for transmitting more than 32 bits contains a 256 byte memory that can be pre-loaded by using the JTAG_FLASH_PAGE_PREP command. An entire 32-bit word must always be followed by a DR-UPDATE. This procedure can be repeated up to 64 times to load a full page of 256 bytes. As long as no test logic reset command is executed, the file register retains its content, but can be overwritten. Its address counter is set to zero each time the command is called. For correct functioning it is necessary to transmit the first word of the register file again during JTAG_SPI_ACCESS.

It is highly recommended to verify the idle state before accessing the SPI bus by executing the JTAG_GET_SPI_BUSY command.

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| Instruction: | 0x 01 | JTAG_SPI_ACCESS | Shift width: 119 bits | | |
|-----------------|-----------|--|-----------------------|--|--|
| | | Access external SPI data flash via JTAG. | | | |
| Shift-in bits: | [118:115] | Number of command bits to be shifted to SPI data flash | | | |
| | [114:109] | Number of address bits to be shifted to SPI data flash | | | |
| | [108:105] | Number of mode bits to be shifted to SPI data flash | | | |
| | [104: 99] | Number of TX data bits to be shifted to SPI data flash | | | |
| | [98: 92] | Number of TX data words to be shifted to SPI data flash | | | |
| | [91: 86] | Number of dummy cycles to be shifted to SPI data flash | | | |
| | [85: 80] | Number of RX data bits to be shifted to SPI data flash | | | |
| | [79: 72] | Command to be transferred to SPI data flash | | | |
| | [71: 64] | Mode to be transferred to SPI data flash | | | |
| | [63: 32] | Address to be transferred to SPI data flash | | | |
| | [31: 0] | TX data word to be transferred to SPI data flash. The byte stream is in big endian while the bytes are in little endian. Must contain the first word when transmitting data using the JTAG_FLASH_PAGE_PREP command. | | | |
| Shift-out bits: | [118: 0] | Don't care | | | |

| Instruction: | 0x 02 | JTAG_FLASH_PAGE_PREP | Shift width: | K · 32 bits |
|-----------------|----------|--|--------------|-------------|
| | | Load data for writing up to one FPGA. Must be followed by 0x 1 | | |
| Shift-in bits: | K·[31:0] | K 32-bit words to be written to one page in the SPI data flash with $1 \le K \le 64$. Each word must be followed by a DR-UPDATE. The byte stream is in big endian while the bytes are in little endian. | | |
| Shift-out bits: | K·[31:0] | Don't care | | |

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Instruction: 0x 03 JTAG_GET_SPI_RXDATA Shift width: 33 bits

Get data read from SPI data flash via after 0x1 -

JTAG_SPI_ACCESS.

Shift-in bits: [32:0] Don't care

Shift-out bits: [32:1] RX data read from SPI data flash

[0] RX data valid flag. Only true if the preceding command was

JTAG_SPI_ACCESS.

Instruction: 0x 04 JTAG_GET_SPI_BUSY Shift width: 1 bit

Checks if the SPI controller is busy. Recommended to use be-

fore any SPI access.

Shift-in bits: [0:0] Don't care

Shift-out bits: [0:0] Obtain SPI bus state:

0b 0: SPI idle0b 1: SPI busy

3.4.7 Boundary-Scan Test

A JTAG IEEE 1149.1–2001 compliant boundary–scan allows to test pin connections without physically probing pins by shifting a boundary–scan register that is composed of cells connected between the FPGA logic and IOs.

The SAMPLE instruction allows to take a snapshot of the input and output signal states without interfering with the device pins. The snapshot is taken on the rising edge of JTAG_TCK in the DR-CAPT state. The data can then be accessed by shifting through the JTAG_TDO output.

The PRELOAD instruction allows scanning of the boundary-scan register without causing interference to the FPGA logic. It allows an initial pattern to be shifted into the boundary-scan register cells.

Both instructions SAMPLE and PRELOAD are combined in the JTAG_SAMPLE_PRELOAD command. While preloading the boundary-scan register cells by shifting data into the input JTAG_TDI the sample results are shifted through the JTAG_TDO output.

The EXTEST instruction allows access to the external circuitry through the device pins. The boundary-scan register cells connected to the output pins are used to apply test stimuli, while those at the input pins capture external signals from the device pins.

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The boundary-scan register length is 317 bits. To enable boundary-scan test, the test-mode register must be set first by using the JTAG_SET_TESTMODE instruction. Please refer to the official Boundary Scan Description Language (BSDL) files for more information.

Instruction: 0x20 JTAG_SET_TESTMODE Shift width: 2 bits

Set value in testmode register.

Shift-in bits: [1:0] Testmode to be set:

0b 00:Disable testmode

0b 01:reserved
0b 10:reserved

0b 11:Boundary-Scan Test

Shift-out bits: [1:0] Don't care

Instruction: 0x 3D JTAG_SAMPLE_PRELOAD Shift width: 317 bits

Boundary-scan SAMPLE and PRELOAD instruction. The

register 0x 20 – Set Testmode must be set to 0b 11.

Shift-in bits: [316:0] Preload value for boundary-scan shift register.

Shift-out bits: [316:0] Sample value of boundary-scan shift register.

Instruction: 0x3E JTAG_EXTEST Shift width: 317 bits

Boundary-scan EXTEST instruction. The register 0x 20 -

Set Testmode must be set to 0b 11.

Shift-in bits: [316:0] Don't care.

Shift-out bits: [316:0] Value of boundary-scan shift register.

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Chapter 4

Electrical Characteristics

Table 4.1: Absolute maximum ratings

| Symbol | Min | Тур | Max | Unit | Description |
|--------------------------|-----|-----|------|------|---|
| | -40 | | 125 | °C | Junction temperature |
| VDD_{IO} | | | 2.75 | V | I/O supply voltage (GPIO banks and VDD_CLK) |
| VDD_{core} | | | 1.20 | V | Core supply voltage (VDD, VDD_PLL, VDD_SER and VDD_SER_PLL) |
| V_{ESD} | | | 4000 | V | HBM ESD class 2 |

Table 4.2: Operation range

| Symbol | Min | Тур | Max | Unit | Description |
|------------------------|------|-----|------|------|--|
| | -20 | | 85 | °C | Operating temperature |
| $VDD_{low.power}$ | 0.85 | 0.9 | 0.95 | V | Core supply voltage (VDD, VDD_PLL) in low power mode |
| $VDD_{economy}$ | 0.95 | 1.0 | 1.05 | V | Core supply voltage (VDD, VDD_PLL) in economy mode |
| VDD_{speed} | 1.05 | 1.1 | 1.15 | V | Core supply voltage (VDD, VDD_PLL) in speed mode |
| VDD_{SER} | 0.95 | | 1.15 | V | SerDes supply voltage (VDD_SER) |
| VDD _{SER_PLL} | 0.95 | | 1.15 | V | SerDes PLL supply voltage (VDD_SER_PLL) |

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Table 4.3: GPIO characteristics in single-ended mode

| Symbol | Min | Тур | Max | Unit | Description |
|-------------------|----------|---------|------------------|--------------------------|---|
| VDD _{IO} | 1.1 | | 2.7 | V | I/O supply voltage (GPIO banks and VDD_CLK) |
| $V_{\rm IN}$ | -0.4 | | $VDD_{IO} + 0.4$ | V | Input voltage range |
| Schmitt-t | rigger i | functio | n disabled: | | |
| V_{IH} | 0.43 | | 0.51 | VDD_{IO} | Input high threshold voltage |
| $V_{\rm IL}$ | 0.45 | | 0.51 | VDD_{IO} | Input low threshold voltage |
| V_{HYST} | | 0 | | V | Hysteresis |
| Schmitt-t | rigger i | functio | n enabled: | | |
| V_{IH} | 0.61 | | 0.67 | VDD_{IO} | Input high threshold voltage |
| $V_{\rm IL}$ | 0.31 | | 0.39 | VDD_{IO} | Input low threshold voltage |
| V_{HYST} | 0.26 | | 0.33 | VDD_{IO} | Hysteresis |
| Output dri | iver dis | abled: | | | |
| ${ m I}_{ m IL}$ | | | 1 | μA | Input pin current when driven active low |
| I_{IH} | | | 1 | μA | Input pin current when driven active high |
| R_{PU} | | 50 | | $k\Omega$ | Pull-up resistance |
| R_{PD} | | 50 | | $k\Omega$ | Pull-down resistance |
| $I_{DD,max}$ | | | 158 | μΑ | Maximum supply current at GPIO input at tran sition point |

Table 4.4: GPIO characteristics in LVDS mode

| Symbol | Min | Тур | Max | Unit | Description |
|-------------------|------|--------------|------|------|--|
| VDD_{IO} | 1.62 | | 2.75 | V | I/O supply voltage |
| I _{out} | | 3.2 | | mA | Output current when LVDS output current boost is set to nominal current |
| I _{out} | | 6.4 | | mA | Output current when LVDS output current boost is set to increased output current |
| VCM_{TX} | | $VDD_{IO}/2$ | | V | Common-mode voltage |
| R _{term} | 90 | 100 | 130 | Ω | |



Table 4.5: PLL characteristics

| Symbol | Min | Тур | Max | Unit | Description |
|-------------------------------|------|-----|--------|--------------------------------|---|
| t_{lock} | | | 1100 | Number of ref. clock cycles | Lock in time (coarse tune, fast-lock mode) with lock detection |
| t_{lock} | | | 57 | Number of ref. clock cycles | Lock in time (coarse tune, fast-lock mode) without lock detection |
| $f_{DCO, low.power}$ | 500 | | 1000 | MHz | DCO frequency in low power mode |
| f _{DCO, economy} | 1000 | | 2000 | MHz | DCO frequency in economy mode |
| $f_{DCO, speed}$ | 1250 | | 2500 | MHz | DCO frequency in speed mode |
| ${ m T}_{ m DCO,step}$ | | | 10 | ps | DCO period tuning step size |
| $f_{\mathrm{PLL, low.power}}$ | | | 250 | MHz | PLL output frequency in low power mode |
| $f_{\text{PLL, economy}}$ | | | 312.5 | MHz | PLL output frequency in economy mode |
| $f_{\rm PLL,speed}$ | | | 416.75 | MHz | PLL output frequency in speed mode |

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Electrical Characteristics

 Table 4.6: Reset characteristics

| Symbol | Min | Тур | Max | Unit | Description |
|--------------------|---------------|------|---------------|------|---|
| V_{DD} | 0.85 | 1.0 | 1.15 | V | Core supply voltage |
| $V_{core,TH+}$ | 0.62 | 0.72 | 0.80 | V | High reset threshold voltage |
| $V_{core,TH-}$ | 0.56 | 0.62 | 0.71 | V | Low reset threshold voltage |
| $V_{core,hyst}$ | 60 | 82 | 96 | mV | Hysteresis voltage |
| SR _{core} | 1.8 | | 180 | V/ms | Supply voltage slew rate |
| VDD_{CLK} | $1.80\pm10\%$ | | $2.50\pm10\%$ | V | VDD_CLK supply voltage |
| = | 1.62 | | 2.75 | V | |
| | | | | | |
| $V_{\rm IO,TH^+}$ | 1.21 | 1.44 | 1.56 | V | High reset threshold voltage ¹ |
| | 1.01 | 1.18 | 1.34 | V | ditto ² |
| | 0.95 | 1.08 | 1.20 | V | ditto ³ |
| | | | | | |
| $V_{\rm IO,TH-}$ | 1.00 | 1.20 | 1.35 | V | Low reset threshold voltage ¹ |
| | 0.89 | 1.06 | 1.19 | V | ditto ² |
| | 0.88 | 0.98 | 1.05 | V | ditto ³ |
| | | | | | |
| $V_{IO,hyst}$ | 152 | 180 | 215 | mV | Hysteresis voltage ¹ |
| | 108 | 126 | 177 | mV | ditto ² |
| | 85 | 100 | 110 | mV | ditto ³ |
| | | | | | |
| SR_{IO} | 1.8 | | 180 | V/ms | Supply voltage slew rate |

¹ No level adjustment, POR_ADJ open.

 $^{^2}$ Level adjustment with R3a $=500\,k\Omega.$

 $^{^3}$ Level adjustment with R3a = 250 k Ω .

Chapter 5 Pinout

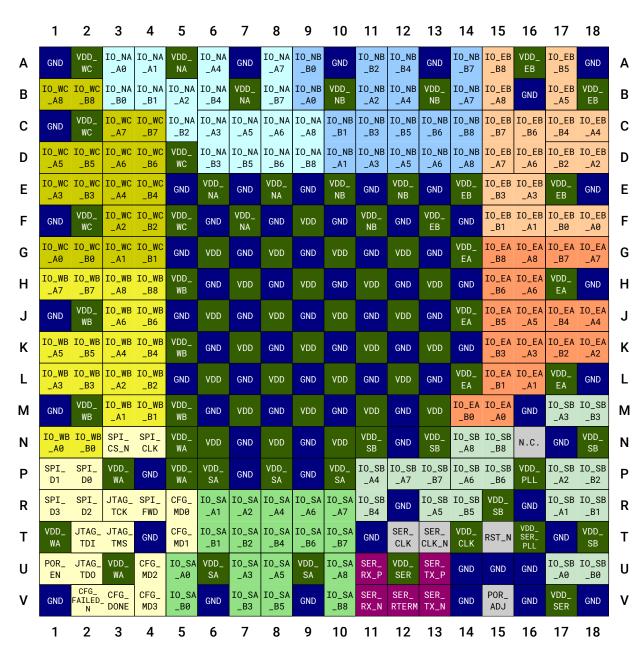
5.1 CCGM1A1 324-Ball FBGA Pinout

The GateMate TM FPGA CCGM1A1 has a 18×18 pin 0.8 mm fine pitch Ball Grid Array (FBGA) package with 324 balls.

General purpose input / output (GPIO) ball arrangement is defined for 4-layer printed circuit board (PCB) layout with only 2 signal layers.

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Pinout

Figure 5.1: CCGM1A1 FBGA pinout

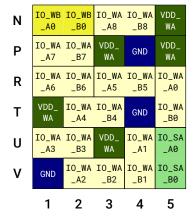


Figure 5.2: Configuration pins of CCGM1A1 FBGA pinout for use as GPIO after configuration



5.2 CCGM1A1 Pinout Description

All ball signals are grouped as shown in Table 5.1.

Table 5.1: Pin types

| Color | Pin type | Number of pins |
|-------|--|-------------------|
| | North GPIO banks NA and NB | |
| | Each bank has 18 GPIO signals and both have separate power supply balls and can be driven individually. GPIO signals are grouped by pairs and each pair can get configured to be either two single ended or a differential pair signal. | 36 |
| | East GPIO banks EA and EB | |
| | Each bank has 18 GPIO signals and both have separate power supply balls and can be driven individually. GPIO signals are grouped by pairs and each pair can get configured to be either two single ended or a differential pair signal. | 36 |
| | South GPIO banks SA and SB | |
| | Each bank has 18 GPIO signals and both have separate power supply balls and can be driven individually. GPIO signals are grouped by pairs and each pair can get configured to be either two single ended or a differential pair signal. | 36 |
| | Configuration pins or west GPIO bank WA alternatively | |
| | The configuration interface consists of 18 pins. After configuration procedure, these balls can be configured to be normal GPIO signals. They are grouped by pairs and each pair can get configured to be either two single ended or a differential pair signal. | 18 |
| | West GPIO banks WB and WC | |
| | Each bank has 18 GPIO signals and both have separate power supply balls and can be driven individually. GPIO signals are grouped by pairs and each pair can get configured to be either two single ended or a differential pair signal. | 36 |
| | Serializer / Deserializer (SerDes) signal pins | |
| | The SerDes interface consits of differential transmit and receive signals and a termination input pin. Furthermore, dedicated power supply exists to the SerDes interface and the SerDes phase-locked loop (PLL) function. | 5 |
| | Power supply pins for FPGA core and GPIO | |
| | The CCGM1A1 core gets supplied from a single power source. The GPIO banks have own power supply pins each. Additionally, some further power supply pins are available for SerDes and other functions. | 78 |

(continued on next page)

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Pinout ____

Table 5.1: Pin types

(continued from previous page)

| Color | Pin type | Number of pins |
|-------|--|-------------------|
| | Ground pins CCGM1A1 has a single ground level for all supply voltages. All ground pins must be connected. | 74 |
| | Any other pins Clock input (single ended or differential)reset input are available in this pin group. | 5 |

Table 5.2: CCGM1A1 Pin list sorted by ball name

| Ball | Signal name | Signal group | Reset category | Description |
|-------------|-------------|-----------------|----------------|----------------------------------|
| A 1 | GND | Ground | 0 | Gound |
| A 2 | VDD_WC | Power | 0 | 3rd GPIO west bank power supply |
| A3 | IO_NA_A0 | GPIO | 1 | 1st GPIO north bank signal A0 |
| A4 | IO_NA_A1 | GPIO | 1 | 1st GPIO north bank signal A1 |
| A 5 | VDD_NA | Power | 0 | 1st GPIO north bank power supply |
| A6 | IO_NA_A4 | GPIO | 1 | 1st GPIO north bank signal A4 |
| A 7 | GND | Ground | 0 | Ground |
| A8 | IO_NA_A7 | GPIO | 1 | 1st GPIO north bank signal A7 |
| A9 | IO_NB_B0 | GPIO | 1 | 2nd GPIO north bank signal B0 |
| A10 | GND | Ground | 0 | Ground |
| A11 | IO_NB_B2 | GPIO | 1 | 2nd GPIO north bank signal B2 |
| A12 | IO_NB_B4 | GPIO | 1 | 2nd GPIO north bank signal B4 |
| A 13 | GND | Ground | 0 | Ground |
| A14 | IO_NB_B7 | GPIO | 1 | 2nd GPIO north bank signal B7 |
| A15 | IO_EB_B8 | GPIO | 1 | 2nd GPIO east bank signal B8 |
| ■ A16 | VDD_EB | Power | 0 | 2nd GPIO east bank power supply |
| A17 | IO_EB_B5 | GPIO | 1 | 2nd GPIO east bank signal B5 |
| A18 | GND | Ground | 0 | Ground |
| B 1 | IO_WC_A8 | GPIO | 1 | 3rd GPIO west bank signal A8 |
| B 2 | IO_WC_B8 | GPIO | 1 | 3rd GPIO west bank signal B8 |
| B3 | IO_NA_B0 | GPIO | 1 | 1st GPIO north bank signal B0 |
| B4 | IO_NA_B1 | GPIO | 1 | 1st GPIO north bank signal B1 |

(continued on next page)



Table 5.2: CCGM1A1 Pin list sorted by ball name

| Ball | Signal name | Signal group | Reset category | Description |
|------------|-------------|-----------------|----------------|----------------------------------|
| B5 | IO_NA_A2 | GPIO | 1 | 1st GPIO north bank signal A2 |
| B6 | IO_NA_B4 | GPIO | 1 | 1st GPIO north bank signal B4 |
| ■ B7 | VDD_NA | Power | 0 | 1st GPIO north bank power supply |
| B8 | IO_NA_B7 | GPIO | 1 | 1st GPIO north bank signal B7 |
| B 9 | IO_NB_A0 | GPIO | 1 | 2nd GPIO north bank signal A0 |
| ■ B10 | VDD_NB | Power | 0 | 2nd GPIO north bank power supply |
| B11 | IO_NB_A2 | GPIO | 1 | 2nd GPIO north bank signal A2 |
| B12 | IO_NB_A4 | GPIO | 1 | 2nd GPIO north bank signal A4 |
| ■ B13 | VDD_NB | Power | 0 | 2nd GPIO north bank power supply |
| B14 | IO_NB_A7 | GPIO | 1 | 2nd GPIO north bank signal A7 |
| B15 | IO_EB_A8 | GPIO | 1 | 2nd GPIO east bank signal A8 |
| B16 | GND | Ground | 0 | Ground |
| B17 | IO_EB_A5 | GPIO | 1 | 2nd GPIO east bank signal A5 |
| ■ B18 | VDD_EB | Power | 0 | 2nd GPIO east bank power supply |
| C1 | GND | Ground | 0 | Ground |
| C2 | VDD_WC | Power | 0 | 3rd GPIO west bank power supply |
| C3 | IO_WC_A7 | GPIO | 1 | 3rd GPIO west bank signal A7 |
| C4 | IO_WC_B7 | GPIO | 1 | 3rd GPIO west bank signal B7 |
| C5 | IO_NA_B2 | GPIO | 1 | 1st GPIO north bank signal B2 |
| C6 | IO_NA_A3 | GPIO | 1 | 1st GPIO north bank signal A3 |
| C7 | IO_NA_A5 | GPIO | 1 | 1st GPIO north bank signal A5 |
| C8 | IO_NA_A6 | GPIO | 1 | 1st GPIO north bank signal A6 |
| C9 | IO_NA_A8 | GPIO | 1 | 1st GPIO north bank signal A8 |
| C10 | IO_NB_B1 | GPIO | 1 | 2nd GPIO north bank signal B1 |
| C11 | IO_NB_B3 | GPIO | 1 | 2nd GPIO north bank signal B3 |
| C12 | IO_NB_B5 | GPIO | 1 | 2nd GPIO north bank signal B5 |
| C13 | IO_NB_B6 | GPIO | 1 | 2nd GPIO north bank signal B6 |
| C14 | IO_NB_B8 | GPIO | 1 | 2nd GPIO north bank signal B8 |
| C15 | IO_EB_B7 | GPIO | 1 | 2nd GPIO east bank signal B7 |
| C16 | IO_EB_B6 | GPIO | 1 | 2nd GPIO east bank signal B6 |
| C17 | IO_EB_B4 | GPIO | 1 | 2nd GPIO east bank signal B4 |
| C18 | IO_EB_A4 | GPIO | 1 | 2nd GPIO east bank signal A4 |
| D1 | IO_WC_A5 | GPIO | 1 | 3rd GPIO west bank signal A5 |
| D2 | IO_WC_B5 | GPIO | 1 | 3rd GPIO west bank signal B5 |

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Pinout ___

Table 5.2: CCGM1A1 Pin list sorted by ball name

(continued from previous page)

| Ball | Signal name | Signal group | Reset category | Description |
|-------------|-------------|-----------------|----------------|----------------------------------|
| ■ D3 | IO_WC_A6 | GPIO | 1 | 3rd GPIO west bank signal A6 |
| D 4 | IO_WC_B6 | GPIO | 1 | 3rd GPIO west bank signal B6 |
| ■ D5 | VDD_WC | Power | 0 | 3rd GPIO west bank power supply |
| D6 | IO_NA_B3 | GPIO | 1 | 1st GPIO north bank signal B3 |
| D7 | IO_NA_B5 | GPIO | 1 | 1st GPIO north bank signal B5 |
| D8 | IO_NA_B6 | GPIO | 1 | 1st GPIO north bank signal B6 |
| D9 | IO_NA_B8 | GPIO | 1 | 1st GPIO north bank signal B8 |
| D10 | IO_NB_A1 | GPIO | 1 | 2nd GPIO north bank signal A1 |
| D11 | IO_NB_A3 | GPIO | 1 | 2nd GPIO north bank signal A3 |
| D12 | IO_NB_A5 | GPIO | 1 | 2nd GPIO north bank signal A5 |
| D13 | IO_NB_A6 | GPIO | 1 | 2nd GPIO north bank signal A6 |
| D14 | IO_NB_A8 | GPIO | 1 | 2nd GPIO north bank signal A8 |
| D15 | IO_EB_A7 | GPIO | 1 | 2nd GPIO east bank signal A7 |
| D16 | IO_EB_A6 | GPIO | 1 | 2nd GPIO east bank signal A6 |
| D17 | IO_EB_B2 | GPIO | 1 | 2nd GPIO east bank signal B2 |
| D18 | IO_EB_A2 | GPIO | 1 | 2nd GPIO east bank signal A2 |
| E 1 | IO_WC_A3 | GPIO | 1 | 3rd GPIO west bank signal A3 |
| E 2 | IO_WC_B3 | GPIO | 1 | 3rd GPIO west bank signal B3 |
| E 3 | IO_WC_A4 | GPIO | 1 | 3rd GPIO west bank signal A4 |
| E 4 | IO_WC_B4 | GPIO | 1 | 3rd GPIO west bank signal B4 |
| E 5 | GND | Ground | 0 | Ground |
| ■ E6 | VDD_NA | Power | 0 | 1st GPIO north bank power supply |
| E 7 | GND | Ground | 0 | Ground |
| ■ E8 | VDD_NA | Power | 0 | 1st GPIO north bank power supply |
| E 9 | GND | Ground | 0 | Ground |
| ■ E10 | VDD_NB | Power | 0 | 2nd GPIO north bank power supply |
| ■ E11 | GND | Ground | 0 | Ground |
| ■ E12 | VDD_NB | Power | 0 | 2nd GPIO north bank power supply |
| E13 | GND | Ground | 0 | Ground |
| ■ E14 | VDD_EB | Power | 0 | 2nd GPIO east bank power supply |
| E15 | IO_EB_B3 | GPIO | 1 | 2nd GPIO east bank signal B3 |
| E16 | IO_EB_A3 | GPIO | 1 | 2nd GPIO east bank signal A3 |
| ■ E17 | VDD_EB | Power | 0 | 2nd GPIO east bank power supply |
| E18 | GND | Ground | 0 | Ground |

(continued on next page)



Table 5.2: CCGM1A1 Pin list sorted by ball name

| Ball | Signal name | Signal group | Reset category | Description |
|-------------|-------------|-----------------|----------------|----------------------------------|
| ■ F1 | GND | Ground | 0 | Ground |
| ■ F2 | VDD_WC | Power | 0 | 3rd GPIO west bank power supply |
| F 3 | IO_WC_A2 | GPIO | 1 | 3rd GPIO west bank signal A2 |
| F 4 | IO_WC_B2 | GPIO | 1 | 3rd GPIO west bank signal B2 |
| ■ F5 | VDD_WC | Power | 0 | 3rd GPIO west bank power supply |
| ■ F6 | GND | Ground | 0 | Ground |
| ■ F7 | VDD_NA | Power | 0 | 1st GPIO north bank power supply |
| ■ F8 | GND | Ground | 0 | Ground |
| ■ F9 | VDD | Power | 0 | Core power supply |
| ■ F10 | GND | Ground | 0 | Ground |
| ■ F11 | VDD_NB | Power | 0 | 2nd GPIO north bank power supply |
| F12 | GND | Ground | 0 | Ground |
| ■ F13 | VDD_EB | Power | 0 | 2nd GPIO east bank power supply |
| F14 | GND | Ground | 0 | Ground |
| F15 | IO_EB_B1 | GPIO | 1 | 2nd GPIO east bank signal B1 |
| F16 | IO_EB_A1 | GPIO | 1 | 2nd GPIO east bank signal A1 |
| F17 | IO_EB_B0 | GPIO | 1 | 2nd GPIO east bank signal B0 |
| F18 | IO_EB_A0 | GPIO | 1 | 2nd GPIO east bank signal A0 |
| G 1 | IO_WC_A0 | GPIO | 1 | 3rd GPIO west bank signal A0 |
| G2 | IO_WC_B0 | GPIO | 1 | 3rd GPIO west bank signal B0 |
| G 3 | IO_WC_A1 | GPIO | 1 | 3rd GPIO west bank signal A1 |
| G 4 | IO_WC_B1 | GPIO | 1 | 3rd GPIO west bank signal B1 |
| G 5 | GND | Ground | 0 | Ground |
| ■ G6 | VDD | Power | 0 | Core power supply |
| G 7 | GND | Ground | 0 | Ground |
| ■ G8 | VDD | Power | 0 | Core power supply |
| G 9 | GND | Ground | 0 | Ground |
| ■ G10 | VDD | Power | 0 | Core power supply |
| G 11 | GND | Ground | 0 | Ground |
| ■ G12 | VDD | Power | 0 | Core power supply |
| G 13 | GND | Ground | 0 | Ground |
| ■ G14 | VDD_EA | Power | 0 | 1st GPIO east bank power supply |
| G15 | IO_EA_B8 | GPIO | 1 | 1st GPIO east bank signal B8 |
| G 16 | IO_EA_A8 | GPIO | 1 | 1st GPIO east bank signal A8 |

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Pinout ____

Table 5.2: CCGM1A1 Pin list sorted by ball name

(continued from previous page)

| Ball | Signal name | Signal group | Reset category | Description |
|-------------|-------------|-----------------|----------------|---------------------------------|
| G 17 | IO_EA_B7 | GPIO | 1 | 1st GPIO east bank signal B7 |
| ■ G18 | IO_EA_A7 | GPIO | 1 | 1st GPIO east bank signal A7 |
| H1 | IO_WB_A7 | GPIO | 1 | 2nd GPIO west bank signal A7 |
| H2 | IO_WB_B7 | GPIO | 1 | 2nd GPIO west bank signal B7 |
| H3 | IO_WB_A8 | GPIO | 1 | 2nd GPIO west bank signal A8 |
| H4 | IO_WB_B8 | GPIO | 1 | 2nd GPIO west bank signal B8 |
| ■ H5 | VDD_WB | Power | 0 | 2nd GPIO west bank power supply |
| ■ H6 | GND | Ground | 0 | Ground |
| ■ H7 | VDD | Power | 0 | Core power supply |
| ■ H8 | GND | Ground | 0 | Ground |
| ■ H9 | VDD | Power | 0 | Core power supply |
| ■ H10 | GND | Ground | 0 | Ground |
| ■ H11 | VDD | Power | 0 | Core power supply |
| ■ H12 | GND | Ground | 0 | Ground |
| ■ H13 | VDD | Power | 0 | Core power supply |
| ■ H14 | GND | Ground | 0 | Ground |
| ■ H15 | IO_EA_B6 | GPIO | 1 | 1st GPIO east bank signal B6 |
| ■ H16 | IO_EA_A6 | GPIO | 1 | 1st GPIO east bank signal A6 |
| ■ H17 | VDD_EA | Power | 0 | 1st GPIO east bank power supply |
| ■ H18 | GND | Ground | 0 | Ground |
| ■ J1 | GND | Ground | 0 | Ground |
| ■ J2 | VDD_WB | Power | 0 | 2nd GPIO west bank power supply |
| J3 | IO_WB_A6 | GPIO | 1 | 2nd GPIO west bank signal A6 |
| J4 | IO_WB_B6 | GPIO | 1 | 2nd GPIO west bank signal B6 |
| ■ J5 | GND | Ground | 0 | Ground |
| ■ J6 | VDD | Power | 0 | Core power supply |
| ■ J7 | GND | Ground | 0 | Ground |
| ■ J8 | VDD | Power | 0 | Core power supply |
| ■ J9 | GND | Ground | 0 | Ground |
| ■ J10 | VDD | Power | 0 | Core power supply |
| ■ J11 | GND | Ground | 0 | Ground |
| ■ J12 | VDD | Power | 0 | Core power supply |
| ■ J13 | GND | Ground | 0 | Ground |
| ■ J14 | VDD_EA | Power | 0 | 1st GPIO east bank power supply |

(continued on next page)



Table 5.2: CCGM1A1 Pin list sorted by ball name

| Ball | Signal name | Signal group | Reset category | Description |
|-------------|-------------|-----------------|----------------|---------------------------------|
| J15 | IO_EA_B5 | GPIO | 1 | 1st GPIO east bank signal B5 |
| J 16 | IO_EA_A5 | GPIO | 1 | 1st GPIO east bank signal A5 |
| J17 | IO_EA_B4 | GPIO | 1 | 1st GPIO east bank signal B4 |
| J18 | IO_EA_A4 | GPIO | 1 | 1st GPIO east bank signal A4 |
| K1 | IO_WB_A5 | GPIO | 1 | 2nd GPIO west bank signal A5 |
| K2 | IO_WB_B5 | GPIO | 1 | 2nd GPIO west bank signal B5 |
| K3 | IO_WB_A4 | GPIO | 1 | 2nd GPIO west bank signal A4 |
| K4 | IO_WB_B4 | GPIO | 1 | 2nd GPIO west bank signal B4 |
| ■ K5 | VDD_WB | Power | 0 | 2nd GPIO west bank power supply |
| ■ K6 | GND | Ground | 0 | Ground |
| ■ K7 | VDD | Power | 0 | Core power supply |
| ■ K8 | GND | Ground | 0 | Ground |
| ■ K9 | VDD | Power | 0 | Core power supply |
| ■ K10 | GND | Ground | 0 | Ground |
| ■ K11 | VDD | Power | 0 | Core power supply |
| K12 | GND | Ground | 0 | Ground |
| ■ K13 | VDD | Power | 0 | Core power supply |
| ■ K14 | GND | Ground | 0 | Ground |
| K15 | IO_EA_B3 | GPIO | 1 | 1st GPIO east bank signal B3 |
| K16 | IO_EA_A3 | GPIO | 1 | 1st GPIO east bank signal A3 |
| K17 | IO_EA_B2 | GPIO | 1 | 1st GPIO east bank signal B2 |
| K18 | IO_EA_A2 | GPIO | 1 | 1st GPIO east bank signal A2 |
| L 1 | IO_WB_A3 | GPIO | 1 | 2nd GPIO west bank signal A3 |
| L2 | IO_WB_B3 | GPIO | 1 | 2nd GPIO west bank signal B3 |
| L 3 | IO_WB_A2 | GPIO | 1 | 2nd GPIO west bank signal A2 |
| L4 | IO_WB_B2 | GPIO | 1 | 2nd GPIO west bank signal B2 |
| L 5 | GND | Ground | 0 | Ground |
| ■ L6 | VDD | Power | 0 | Core power supply |
| ■ L7 | GND | Ground | 0 | Ground |
| ■ L8 | VDD | Power | 0 | Core power supply |
| ■ L9 | GND | Ground | 0 | Ground |
| ■ L10 | VDD | Power | 0 | Core power supply |
| ■ L11 | GND | Ground | 0 | Ground |
| ■ L12 | VDD | Power | 0 | Core power supply |

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Pinout ____

Table 5.2: CCGM1A1 Pin list sorted by ball name

(continued from previous page)

| Ball | Signal name | Signal group | Reset category | Description |
|-------|----------------------|-----------------|----------------|---|
| ■ L13 | GND | Ground | 0 | Ground |
| ■ L14 | VDD_EA | Power | 0 | 1st GPIO east bank power supply |
| L15 | IO_EA_B1 | GPIO | 1 | 1st GPIO east bank signal B1 |
| L16 | IO_EA_A1 | GPIO | 1 | 1st GPIO east bank signal A1 |
| ■ L17 | VDD_EA | Power | 0 | 1st GPIO east bank power supply |
| ■ L18 | GND | Ground | 0 | Ground |
| ■ M1 | GND | Ground | 0 | Ground |
| ■ M2 | VDD_WB | Power | 0 | 2nd GPIO west bank power supply |
| M3 | IO_WB_A1 | GPIO | 1 | 2nd GPIO west bank signal A1 |
| M4 | IO_WB_B1 | GPIO | 1 | 2nd GPIO west bank signal B1 |
| ■ M5 | VDD_WB | Power | 0 | 2nd GPIO west bank power supply |
| ■ M6 | GND | Ground | 0 | Ground |
| ■ M7 | VDD | Power | 0 | Core power supply |
| ■ M8 | GND | Ground | 0 | Ground |
| ■ M9 | VDD | Power | 0 | Core power supply |
| ■ M10 | GND | Ground | 0 | Ground |
| ■ M11 | VDD | Power | 0 | Core power supply |
| ■ M12 | GND | Ground | 0 | Ground |
| ■ M13 | VDD | Power | 0 | Core power supply |
| ■ M14 | IO_EA_B0 | GPIO | 1 | 1st GPIO east bank signal B0 |
| ■ M15 | IO_EA_A0 | GPIO | 1 | 1st GPIO east bank signal A0 |
| ■ M16 | GND | Ground | 0 | Ground |
| ■ M17 | IO_SB_A3 | GPIO | 1 | 2nd GPIO south bank signal A3 |
| ■ M18 | IO_SB_B3 | GPIO | 1 | 2nd GPIO south bank signal B3 |
| N1 | IO_WB_A0 | GPIO | 1 | 2nd GPIO west bank signal A0 |
| N2 | IO_WB_B0 | GPIO | 1 | 2nd GPIO west bank signal B0 |
| N3 | SPI_CS_N IO_WA_A8 | GPIO GPIO | 3 1 | 1 st function: Configuration SPI chip select 2 nd function: 1st GPIO west bank signal A8 |
| N4 | SPI_CLK IO_WA_B8 | GPIO GPIO | 3 1 | 1 st function: Configuration SPI clock 2 nd function: 1st GPIO west bank signal B8 |
| ■ N5 | VDD_WA | Power | 0 | 1st GPIO west bank power supply |
| ■ N6 | VDD | Power | 0 | Core power supply |
| ■ N7 | GND | Ground | 0 | Ground |
| ■ N8 | VDD | Power | 0 | Core power supply |

(continued on next page)



Table 5.2: CCGM1A1 Pin list sorted by ball name

| Ball | Signal name | Signal group | Reset category | Description |
|------------|--------------------|-----------------|----------------|--|
| ■ N9 | GND | Ground | 0 | Ground |
| ■ N10 | VDD | Power | 0 | Core power supply |
| ■ N11 | VDD_SB | Power | 0 | 2nd GPIO south bank power supply |
| ■ N12 | GND | Ground | 0 | Ground |
| ■ N13 | VDD_SB | Power | 0 | 2nd GPIO south bank power supply |
| N14 | IO_SB_A8 CLK0 | GPIO GPIO | 1 1 | 1 st function: 2nd GPIO south bank signal A8 2 nd function: 1st clock input |
| N15 | IO_SB_B8 | GPIO | 1 | 2nd GPIO south bank signal B8 |
| ■ N16 | N.C. | Other | 0 | Not connected. This pin must be left open. |
| ■ N17 | GND | Ground | 0 | Ground |
| ■ N18 | VDD_SB | Power | 0 | 2nd GPIO south bank power supply |
| ■ P1 | SPI_D1 IO_WA_A7 | GPIO GPIO | 4 1 | 1 st function: Configuration SPI data bit 1 2 nd function: 1st GPIO west bank signal A7 |
| P2 | SPI_D0 IO_WA_B7 | GPIO GPIO | 3 1 | 1 st function: Configuration SPI data bit 0 2 nd function: 1st GPIO west bank signal B7 |
| ■ P3 | VDD_WA | Power | 0 | 1st GPIO west bank power supply |
| P4 | GND | Ground | 0 | Ground |
| ■ P5 | VDD_WA | Power | 0 | 1st GPIO west bank power supply |
| ■ P6 | VDD_SA | Power | 0 | 1st GPIO south bank power supply |
| P 7 | GND | Ground | 0 | Ground |
| ■ P8 | VDD_SA | Power | 0 | 1st GPIO south bank power supply |
| P 9 | GND | Ground | 0 | Ground |
| ■ P10 | VDD_SA | Power | 0 | 1st GPIO south bank power supply |
| P11 | IO_SB_A4 | GPIO | 1 | 2nd GPIO south bank signal A4 |
| P12 | IO_SB_A7 CLK1 | GPIO GPIO | 1 1 | 1 st function: 2nd GPIO south bank signal A7 2 nd function: 2nd clock input |
| P13 | IO_SB_B7 | GPIO | 1 | 2nd GPIO south bank signal B7 |
| ■ P14 | IO_SB_A6 CLK2 | GPIO GPIO | 1 1 | 1 st function: 2nd GPIO south bank signal A6 2 nd function: 3rd clock input |
| P15 | IO_SB_B6 | GPIO | 1 | 2nd GPIO south bank signal B6 |
| ■ P16 | VDD_PLL | Power | 0 | PLL power supply |
| P17 | IO_SB_A2 | GPIO | 1 | 2nd GPIO south bank signal A2 |
| P18 | IO_SB_B2 | GPIO | 1 | 2nd GPIO south bank signal B2 |
| R 1 | SPI_D3 IO_WA_A6 | GPIO GPIO | 4 1 | 1 st function: Configuration SPI data bit 3 2 nd function: 1st GPIO west bank signal A6 |

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Pinout ___

Table 5.2: CCGM1A1 Pin list sorted by ball name

(continued from previous page)

| Ball | Signal name | Signal group | Reset category | Description |
|------------|----------------------|-----------------|----------------|--|
| R2 | SPI_D2 IO_WA_B6 | GPIO GPIO | 4 1 | 1 st function: Configuration SPI data bit 2 2 nd function: 1st GPIO west bank signal B6 |
| R3 | JTAG_TCK IO_WA_A5 | GPIO GPIO | 4 1 | 1 st function: Configuration JTAG clock 2 nd function: 1st GPIO west bank signal A5 |
| R4 | SPI_FWD IO_WA_B5 | GPIO GPIO | 2 1 | 1 st function: Configuration SPI data forward 2 nd function: 1st GPIO west bank signal B5 |
| R 5 | CFG_MD0 IO_WA_A0 | GPIO GPIO | 4 1 | 1 st function: Configuration mode bit 0 2 nd function: 1st GPIO west bank signal A0 |
| R 6 | IO_SA_A1 | GPIO | 1 | 1st GPIO south bank signal A1 |
| ■ R7 | IO_SA_A2 | GPIO | 1 | 1st GPIO south bank signal A2 |
| ■ R8 | IO_SA_A4 | GPIO | 1 | 1st GPIO south bank signal A4 |
| R 9 | IO_SA_A6 | GPIO | 1 | 1st GPIO south bank signal A6 |
| R10 | IO_SA_A7 | GPIO | 1 | 1st GPIO south bank signal A7 |
| R11 | IO_SB_B4 | GPIO | 1 | 2nd GPIO south bank signal B4 |
| R12 | GND | Ground | 0 | Ground |
| R13 | IO_SB_A5 CLK3 | GPIO GPIO | 1 1 | 1 st function: 2nd GPIO south bank signal A5 2 nd function: 4th clock input |
| R14 | IO_SB_B5 | GPIO | 1 | 2nd GPIO south bank signal B5 |
| ■ R15 | VDD_SB | Power | 0 | 2nd GPIO south bank power supply |
| R16 | GND | Ground | 0 | Ground |
| R17 | IO_SB_A1 | GPIO | 1 | 2nd GPIO south bank signal A1 |
| R18 | IO_SB_B1 | GPIO | 1 | 2nd GPIO south bank signal B1 |
| ■ T1 | VDD_WA | Power | 0 | 1st GPIO west bank power supply |
| T2 | JTAG_TDI IO_WA_A4 | GPIO GPIO | 4 1 | 1 st function: JTAG data input 2 nd function: 1st GPIO west bank signal A4 |
| T3 | JTAG_TMS IO_WA_B4 | GPIO GPIO | 4 1 | 1 st function: JTAG test mode select 2 nd function: 1st GPIO west bank signal B4 |
| T 4 | GND | Ground | 0 | Ground |
| T5 | CFG_MD1 IO_WA_B0 | GPIO GPIO | 4 1 | 1 st function: Configuration mode bit 1 2 nd function: 1st GPIO west bank signal BO |
| T 6 | IO_SA_B1 | GPIO | 1 | 1st GPIO south bank signal B1 |
| T 7 | IO_SA_B2 | GPIO | 1 | 1st GPIO south bank signal B2 |
| T 8 | IO_SA_B4 | GPIO | 1 | 1st GPIO south bank signal B4 |
| T 9 | IO_SA_B6 | GPIO | 1 | 1st GPIO south bank signal B6 |
| T10 | IO_SA_B7 | GPIO | 1 | 1st GPIO south bank signal B7 |
| ■ T11 | GND | Ground | 0 | Ground |

(continued on next page)



Table 5.2: CCGM1A1 Pin list sorted by ball name

| Ball | Signal name | Signal group | Reset category | Description |
|-------------|----------------------|-----------------|----------------|---|
| ■ T12 | SER_CLK | Other | 4 | SerDes clock, positive LVDS signal (or common use clock, single ended) |
| ■ T13 | SER_CLK_N | Other | 1 | SerDes clock, negative LVDS signal |
| ■ T14 | VDD_CLK | Power | 0 | Clock signal power supply |
| ■ T15 | RST_N | Other | 4 | Reset |
| ■ T16 | VDD_SER_PLL | Power | 0 | SerDes PLL power supply (1.0 V to 1.1 V $\pm 50 \text{mV}$) |
| ■ T17 | GND | Ground | 0 | Ground |
| ■ T18 | VDD_SB | Power | 0 | 2nd GPIO south bank power supply |
| U 1 | POR_EN IO_WA_A3 | GPIO GPIO | 2 1 | 1 st function: Enable power-on reset 2 nd function: 1st GPIO west bank signal A3 |
| U 2 | JTAG_TDO IO_WA_B3 | GPIO GPIO | 2 1 | 1 st function: JTAG data output 2 nd function: 1st GPIO west bank signal B3 |
| ■ U3 | VDD_WA | Power | 0 | 1st GPIO west bank power supply |
| U 4 | CFG_MD2 IO_WA_A1 | GPIO GPIO | 4 1 | 1 st function: Configuration mode bit 2 2 nd function: 1st GPIO west bank signal A1 |
| ■ U5 | IO_SA_A0 | GPIO | 1 | 1st GPIO south bank signal A0 |
| ■ U6 | VDD_SA | Power | 0 | 1st GPIO south bank power supply |
| U 7 | IO_SA_A3 | GPIO | 1 | 1st GPIO south bank signal A3 |
| ■ U8 | IO_SA_A5 | GPIO | 1 | 1st GPIO south bank signal A5 |
| ■ U9 | VDD_SA | Power | 0 | 1st GPIO south bank power supply |
| ■ U10 | IO_SA_A8 | GPIO | 1 | 1st GPIO south bank signal A8 |
| ■ U11 | SER_RX_P | SerDes | 1 | Receive data line, positive LVDS signal |
| ■ U12 | VDD_SER | Power | 0 | SerDes core power supply (1.0 V to 1.1 V $\pm 50 \mathrm{mV}$) |
| ■ U13 | SER_TX_P | SerDes | 1 | Transmit data line, positive LVDS signal |
| ■ U14 | GND | Ground | 0 | Ground |
| ■ U15 | GND | Ground | 0 | Ground |
| ■ U16 | GND | Ground | 0 | Ground |
| U 17 | IO_SB_A0 | GPIO | 1 | 2nd GPIO south bank signal A0 |
| U18 | IO_SB_B0 | GPIO | 1 | 2nd GPIO south bank signal B0 |
| ■ V1 | GND | Ground | 0 | Ground |
| V2 | CFG_FAILED_N | GPIO | 2 | 1 st function: Configuration failed signal |
| | IO_WA_A2 | GPIO | 1 | 2 nd function: 1st GPIO west bank signal A2 |
| V3 | CFG_DONE IO_WA_B2 | GPIO GPIO | 2 1 | 1 st function: Configuration done signal 2 nd function: 1st GPIO west bank signal B2 |

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Pinout ____

Table 5.2: CCGM1A1 Pin list sorted by ball name

(continued from previous page)

| Ball | Signal name | Signal group | Reset category | Description | |
|------------|-------------|-----------------|----------------|--|--|
| V 4 | CFG_MD3 | GPIO | 4 | 1 st function: Configuration mode bit 3 | |
| | IO_WA_B1 | GPIO | 1 | 2 nd function: 1st GPIO west bank signal B1 | |
| ■ V5 | IO_SA_B0 | GPIO | 1 | 1st GPIO south bank signal B0 | |
| ■ V6 | GND | Ground | 0 | Ground | |
| ■ V7 | IO_SA_B3 | GPIO | 1 | 1st GPIO south bank signal B3 | |
| ■ V8 | IO_SA_B5 | GPIO | 1 | 1st GPIO south bank signal B5 | |
| ■ V9 | GND | Ground | 0 | Ground | |
| ■ V10 | IO_SA_B8 | GPIO | 1 | 1st GPIO south bank signal B8 | |
| ■ V11 | SER_RX_N | SerDes | 1 | Receive data line, negative LVDS signal | |
| ■ V12 | SER_RTERM | SerDes | 0 | Line termination | |
| ■ V13 | SER_TX_N | SerDes | 1 | Transmit data line, negative LVDS signal | |
| ■ V14 | GND | Ground | 0 | Ground | |
| ■ V15 | POR_ADJ | Other | 0 | Power-on-Reset level adjustment | |
| ■ V16 | GND | Ground | 0 | Ground | |
| ■ V17 | VDD_SER | Power | 0 | SerDes core power supply (1.0 V to 1.1 V $\pm 50 \text{mV}$) | |
| ■ V18 | GND | Ground | 0 | Ground | |

Reset categories:

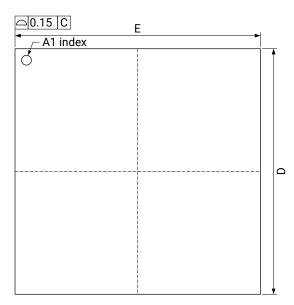
- **0**: No reset (supply or analog input pin)
- 1: Pin disabled, high-z
- **2:** Pin characteristic already during reset state
- 3: Pin characteristic depends on the configuration mode (SPI master: I/O, else: input)
- **4:** Input pin

Chapter 6

Mechanical Dimensions

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Top view

| Ref. | Dime | ensions in | mm | |
|------|------------|------------|--------|--|
| Rei. | Min | Nom | Max | |
| Α | 1.080 | 1.190 | 1.300 | |
| A1 | 0.300 | 0.350 | 0.400 | |
| A2 | 0.780 | 0.840 | 0.900 | |
| Øb | 0.400 | 0.450 | 0.500 | |
| D | 14.900 | 15.000 | 15.100 | |
| Ε | 14.900 | 15.000 | 15.100 | |
| D1 | 13.600 BSC | | | |
| E1 | 13.600 BSC | | | |
| SE | 0.400 BSC | | | |
| SD | | 0.400 BSC | ; | |
| е | | 0.800 BSC | ; | |
| | | | | |

- All dimensions and tolerances are conform to ASME Y14.5M-1994.
- Compliant to JEDEC registered outline MO-275.
- Ultra low alpha compound.

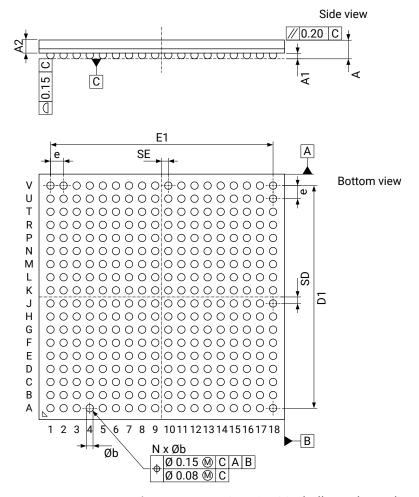


Figure 6.1: FATC FBGA 324 balls package dimensions

Acronyms

| ADPLL | all-digital phase-locked loop | 41 |
|---------|------------------------------------|--|
| AI | artificial intelligence | 13 |
| | | |
| BSDL | Boundary Scan Description Language | 70 |
| | | |
| CP-line | carry & propagation signal line | 19, 49 |
| CPE | Cologne Programmable Element | 5, 6, 11, 17–19, 23–25, 29, 43, 49, 50 |
| | | |
| DCO | digitally controlled oscillator | 41, 75 |
| DDR | double data rate | 14 |
| DPSRAM | dual port SRAM | 5, 11, 17, 18, 23, 26, 28, 29, 33 |
| | | |
| ECC | error checking and correcting | 14, 24–26, 30, 31 |
| ESD | Electrocstatic discharge | 73 |
| | | |
| FBGA | fine pitch Ball Grid Array | 6, 10, 15, 77, 78, 91 |
| FIFO | first-in, first-out memory | 5-7, 14, 24-26, 33-40 |
| FPGA | field-programmable gate array | 13, 20, 47, 79 |
| FSM | finite-state machine | 6, 64, 67 |
| | | |
| GPIO | general purpose input / output | 5-7, 11, 14, 17, 20, 21, 41, 43, 44, 50, 51, 73, 77-79 |
| | | |

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___ Acronyms ___

| HBM | Human Body Model | 73 |
|----------|---|------------------------------------|
| HDL | Hardware Description Language | 45 |
| | | |
| IM | Input Multiplexer | 11, 42, 43 |
| IoT | Internet of Things | 13 |
| IPCEI | Important Project of Common European In- | 13 |
| | terest | |
| | | |
| JSON | JavaScript Object Notation (data inter- change format) | 48 |
| JTAG | Joint Test Action Group | 6, 10, 15, 17, 41, 47, 51, 52, 58, |
| JIAG | John Test Action Group | 63–70 |
| | | |
| LSB | least significant bit | 64, 67 |
| LUT | lookup table | 47, 48 |
| LUT-2 | 2-input lookup table | 18 |
| LUT-tree | tree-structure lookup table | 14, 47 |
| LVCMOS | low voltage CMOS | 21 |
| LVDS | low-voltage differential signaling | 5, 7, 14, 20, 21, 73 |
| | | |
| MUX-4 | 4-input multiplexer | 18 |
| | | |
| OM | Output Multiplexer | 11, 42, 43 |
| | | |
| PCB | printed circuit board | 13, 15, 77 |
| PLL | phase-locked loop | 7, 11, 14, 17, 41, 44, 61, 73, 75, |
| DOD | novyou on wood | 79 |
| POR | power-on reset | 6, 54–56 |
| RAM | random-access memory | 5, 10, 23–27, 29–33, 47 |
| ROM | read-only memory | 24, 32 |
| RTL | Register Transfer Level | 45 |
| KIL | Register Transfer Level | 40 |
| SB | Switch Box | 6, 11, 17, 25, 42, 43, 50 |
| SDF | Standard Delay Format | 45, 49 |
| SDP | simple dual port | 5, 7, 14, 23, 24, 26–29, 31, 32, |
| | • | 34, 35 |
| | | |

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___ Acronyms ___



| SerDes | Serializer / Deserializer | 11 17 17 71 77 70 |
|--------|--|------------------------------------|
| | • | 11, 14, 17, 41, 44, 73, 79 |
| SLP | Super Low Power | 13 |
| SPI | Serial Peripheral Interface | 6, 15, 17, 41, 47, 50, 52, 58, 60, |
| | | 61, 63, 66–70 |
| SRAM | static random-access memory | 14, 18, 29, 34 |
| STA | static timing analysis | 45 |
| | | |
| TAP | Test Access Point | 63-68 |
| TCK | Test Clock | 63, 64 |
| TDI | Test Data Input | 63, 64 |
| TDO | Test Data Output | 63, 64 |
| TDP | true dual port | 5, 7, 14, 23, 24, 26–29, 31, 32, |
| | - | 34, 35 |
| TMS | Test Mode Select | 63, 64 |
| | | |
| VHDL | Very High Speed Integrated Circuit Hard- | 45 |
| V1122 | ware Description Language | .5 |
| | | |
| Yosys | Yosys Open SYnthesis Suite | 10, 45, 47, 48 |
| 103y3 | 100yo Open officiesis outc | 10, 77, 77, 70 |

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